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# Optoelectronic insights of lead-free layered halide perovskites

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Two-dimensional organic–inorganic halide perovskites have emerged as promising candidates for a multitude of optoelectronic technologies, owing to their versatile structure and electronic properties. The optical and electronic properties are harmoniously integrated with both the inorganic metal halide octahedral slab, and the organic spacer layer. The inorganic octahedral layers can also assemble into periodically stacked nanoplatelets, which are interconnected by the organic ammonium cation, resulting in the formation of a superlattice or superstructure. In this perspective, we explore the structural, electronic, and optical properties of lead-free hybrid halides, and the layered halide perovskite single crystals and nanostructures, expanding our understanding of the diverse applications enabled by these versatile structures. The optical properties of the layered halide perovskite single crystals and superlattices are a function of the organic spacer layer thickness, the metal center with either divalent or a combination of monovalent and trivalent cations, and the halide composition. The distinct absorption and emission features are guided by the structural deformation, electron–phonon coupling, and the polaronic effect. Among the diverse optoelectronic possibilities, we have focused on the photodetection capability of layered halide perovskite single crystals, and elucidated the descriptors such as excitonic band gap, effective mass, carrier mobility, Rashba splitting, and the spin texture that decides the direct component of the optical transitions.

## Introduction

In recent years, organic–inorganic lead halide perovskites ( $ABX_3$ ; where  $A = Cs^+$ ,  $CH_3NH_3^+$ ,  $MA^+$ ,  $HC(NH_2)_2^+$ ,  $FA^+$ ,  $B = Pb^{2+}$

and  $X = Cl^-$ ,  $Br^-$  and  $I^-$ ) have emerged as promising photo-absorbers in the field of optoelectronics and photovoltaics.<sup>1</sup> The dynamically tuneable crystal structure, and soft lattice contribute to their versatile properties, and bestow upon them nonclassical semiconductor features. The favourable optical and electronic properties, including a suitable absorption coefficient, carrier diffusion length, exciton binding energy ( $E_b$ ), and defect tolerance, contribute to the outstanding

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performance of hybrid perovskites in various optoelectronic devices, such as photodetector, light emitting diode (LED), field effect transistor (FET), *etc.*<sup>2,3</sup> Also, there has been a remarkable increase in the power conversion efficiency of perovskite solar cells, witnessing a surge from 3.8% to an impressive 26.1% within a very short span of time.<sup>4</sup>

Despite their advantages, the lead-based hybrid perovskites encounter stability issues in the presence of heat and moisture.<sup>5,6</sup> Furthermore, the conventional ABX<sub>3</sub> perovskites containing toxic Pb are not recommended in various optoelectronic technologies. The high solubility of lead halide perovskites in water poses a significant environmental risk, as their leaching into the environment endangers the local biological system. While new methods have been developed for stringent encapsulation of the perovskite to prevent lead leakage, uncertainties persist regarding the overall outcome for long-term storage, and production.

In response, the lead-free halide perovskites have emerged as viable alternatives. In this class of stable perovskites, the toxic Pb<sup>2+</sup> center is substituted with either a divalent lead-free cation, or a combination of monovalent and trivalent metal centers.<sup>7,8</sup> The immediate elements with similar electronic configurations to Pb<sup>2+</sup>, such as Bi<sup>3+</sup> and Sn<sup>2+</sup>, are considered less harmful. When the B-site of hybrid halides contains elements such as Bi, Sb, In, or transition metals, they tend to predominantly form lower-dimensional systems. Moreover, the ABX<sub>3</sub> type 3D perovskites with Sn<sup>2+</sup> at the B-site are typically unstable due to the propensity for the formation of Sn<sup>4+</sup> state under ambient conditions. To address this issue, introducing a hydrophobic organic cation in the A-site, which acts as a spacer cation, offers both structural and chemical stability in the system. The dimension reduction of metal halide perovskites induces better ambient stability, leading to the classification of these materials as two-dimensional (2D) layered halide perovskites.

The layered halide perovskites are crafted through a structural modification of the 3D perovskites (Fig. 1). They are composed of either single or multiple layers of inorganic

building blocks, strategically separated by the bulky organic spacer cation, with the coordination sites being satisfied by the halide ions. The 3D perovskite unit cell can be cleaved along ⟨100⟩, ⟨110⟩, or ⟨111⟩ planes, resulting in the differently oriented layered halide perovskites, respectively. Among these perovskites, those with ⟨100⟩ crystallographic orientation is extensively studied, and Fig. 1 illustrates the cleavage along the ⟨100⟩ direction. The 2D halide perovskites are further categorised into Ruddlesden-Popper (RP), Dion-Jacobson (DJ), and alternating cation interlayer space (ACI) phases. The RP and DJ phases can be represented by the formulae A'<sub>2</sub>A<sub>n-1</sub>M<sub>n</sub>X<sub>3n+1</sub>, and A'<sup>′</sup>A<sub>n-1</sub>M<sub>n</sub>X<sub>3n+1</sub>, where A' and A'′ are the monovalent, and divalent organic cations, respectively.<sup>9</sup> ACI phase with the general formula A'<sup>′</sup>A<sub>n</sub>M<sub>n</sub>X<sub>3n+1</sub>, notably includes the guanidinium (GA), and MA spacer cations.<sup>10</sup> Here, *n* represents the number of octahedral layers in the inorganic block.

In the RP phase, two parallel inorganic layers are staggered by half a unit cell (1/2, 1/2 displacement in the in-plane direction) because two successive inorganic slabs are connected by two monoammonium cations, creating a van der Waals gap between them (Fig. 1).<sup>10</sup> In the DJ phases, the inorganic layers are joined by a single diammonium cation, resulting in an eclipsed stacking configuration where the inorganic layers are directly on top of each other (0, 0 displacement). For the ACI phase with a displacement of (0, 1/2), the inorganic layers appear eclipsed from *a* direction but staggered from the *b* direction. The A-site cation occupies the interior of the cuboctahedral cage, alternating with another cation within the lattice. Experimental observations indicate that the connectivity modes of the octahedral layers in such structures are predominantly through corner, edge, or face sharing. All of these connectivity modes are primarily governed by factors such as the nature of hydrogen bonding, the space-filling ability within the lattice, the rigidity of the spacer cations, the size of the spacer cations, and the nature of halide ions. All of these factors collectively determine the crystal structure of the 2D phase and its corresponding space groups.<sup>10</sup> In A'<sub>2</sub>A<sub>n-1</sub>M<sub>n</sub>X<sub>3n+1</sub>, and A'<sup>′</sup>A<sub>n-1</sub>M<sub>n</sub>X<sub>3n+1</sub>, when M consists of a combination of monovalent and trivalent cations, it results in the formation of hybrid layered double perovskites (HLDP).<sup>11</sup> The crystallization behaviour of HLDPs is contingent on the specific type of organic cation employed, resulting in the potential to exhibit either the RP or DJ phase (Fig. 1).

The incorporation of organic layers in layered halide perovskites acts as a barrier, preventing the penetration of water molecules into the crystal structures, and inhibiting halide ion migration.<sup>12,13</sup> In conventional 3D perovskite halides (ABX<sub>3</sub>), ion migration is more pronounced due to the lower activation energy (*E*<sub>a</sub>) for A<sup>+</sup> cation, and the halide (X<sup>-</sup>).<sup>14</sup> Conversely, the B<sup>2+</sup> cations (either Pb<sup>2+</sup> or Sn<sup>2+</sup>) exhibit higher *E*<sub>a</sub>, and thus do not participate significantly in ion migration. The layered halide perovskites exhibit lower ion migration compared to their 3D counterparts, due to the presence of bulky organic spacers between the inorganic layers. These spacers discourage the migration of A<sup>+</sup> cations, and hinder halide migration through the formation of strong hydrogen bonds.<sup>13</sup> Since, the ion migration is independent of the B-site cations, both the lead



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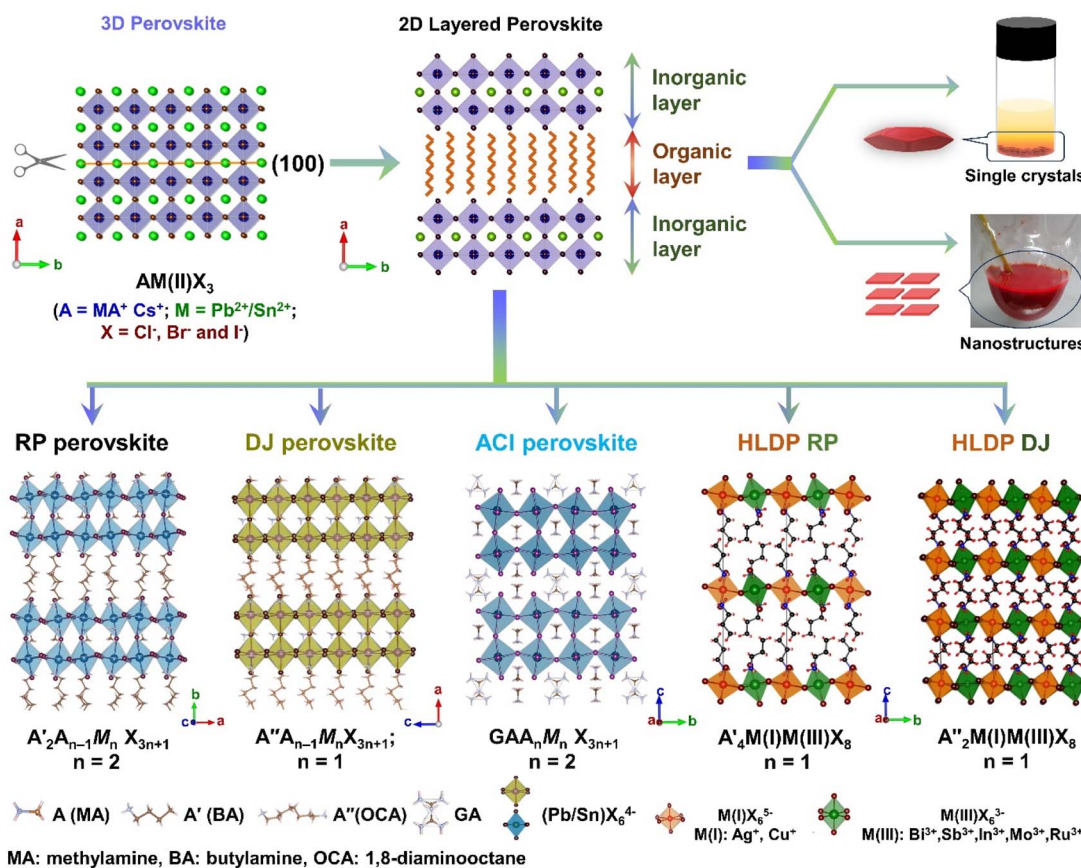


Fig. 1 Schematic representation of the transformation from the 3D to 2D layered halide perovskites along (100), and their existence as single crystals, and NPLs (top panel). Basic structural classification of the layered halide perovskite into major categories: RP, DJ, ACI, HLDP RP, and HLDP DJ (bottom panel).

and non-lead layered halide perovskites exhibit decreased ion migration.

The optoelectronic properties of the layered halide perovskites are intriguing due to their structural flexibility, which facilitates quantum confinement, dielectric confinement, exciton binding energy, carrier dynamics, tuneable band gap, and the desired band alignment.<sup>15</sup> These systems create multiple quantum well (QW) structures characterized by varying degrees of quantum confinement, with the inorganic and organic layers acting as the well and barrier, respectively. With increasing layer numbers ( $n$ ) in the inorganic slabs, the QW width is widened, which consequently decreases the band gap. This trend is advantageous for achieving longer diffusion lengths, and high carrier mobility in the photovoltaic devices. The intrinsic optoelectronic characteristics and structural orientations, and distortions can be modified by simply changing the spacer cations. This versatility paves the way for a wide range of applications, including quantum computation, LED, FET, X-ray detection and scintillation, solar cell, and photodetector.

The above dimension reduction involves a structural re-orientation of the unit cell, without any analogy to the morphological reduction in nanostructures. Apart from the single crystals, the layered halide perovskites can be

synthesized in the form of nanostructures, with the specific outcome depending on the chosen synthetic procedure. In general, the synthesis of single crystals involves slow cooling or slow evaporation methods,<sup>9,16</sup> while the incorporation of surfactants in the reaction medium tends to form the nanocrystals (NCs) or nanoplatelets (NPLs).<sup>17</sup> The dominion of a nanostructure is governed by size-dependent properties arising from the variations in crystallite size, while maintaining the same fundamental structural framework across all entities within the structure. Examples like  $CsPbBr_3$ ,  $MAPbBr_3$  and  $FAPbI_3$  demonstrate 3D perovskite structures, but each exhibiting distinct morphological counterparts such as NCs, nano-sheets (NSs), nanorods, *etc.*<sup>18</sup> For the layered halide perovskites, the thin NS/NPLs consist of inorganic blocks interconnected by organic amine spacer cations, resulting in a distinct multilayer diffraction pattern corresponding to a superlattice or superstructure. The reported 2D nanostructures are predominantly oriented along  $\langle 00l \rangle$ , in contrast to the 2D bulk single crystals. The exploration of such perovskite superlattices is still in its early stages and has a long way to progress.

After delineating the distinctive characteristics of lead-free 2D halide perovskites in this section, our discussion in the subsequent sections commences with an exploration of the descriptors influencing the optoelectronic properties of hybrid



perovskites. Following this, we delve into the structural and optical properties of low-dimensional hybrid halides. We extensively discuss the optical properties of Sn-based layered halide perovskites. Subsequently, we examine the layered halide perovskites with multiple metal centers, namely HLDP, and vacancy ordered layered double perovskites. The structural evolution of 2D superlattices is then presented. We elaborate on the optoelectronic properties, especially focusing on Sn-based layered halide perovskites, with distinct attention given to potential-biased and self-powered photodetectors. Finally, we offer our perspective on the overarching theme, highlighting the challenges in this field.

## Descriptors guiding the optoelectronic properties

### Band gap

The energy gap between the conduction band minima (CBM) and valence band maxima (VBM) stands out as a fundamental parameter steering the performance of any semiconductor. In layered halide perovskites, the band gap is regulated by the electronic contributions from both the inorganic block, and the organic spacer layer. Four distinct types of band alignment—type Ia, Ib, IIa, and IIb contribute to the nuanced understanding of their optoelectronic properties. In type Ia, only the inorganic slab contributes to the VBM and CBM edges, while in type Ib, the organic spacer contributes. This configuration proves advantageous for LEDs, and lasers for maintaining an optimal PLQY. Conversely, in type IIa, the CB and VB edges have contributions from the organic and inorganic layers, respectively, and *vice versa* for type IIb. As a result, the carriers are spatially separated into distinct layers, making this arrangement favourable for photodetectors and solar cells.<sup>19–21</sup> A lower band gap enhances the light-harvesting capabilities, proving advantageous for photodetectors, and solar cells.

The band gap of 3D perovskites can be altered by cation substitution leading to structural distortion. The band gap is expanded by introducing  $\text{PbI}_6^{4-}$  octahedral tilting when a smaller cation such as  $\text{Cs}^+$  partially replaces  $\text{FA}^+$  in  $\text{FAPbI}_3$ .<sup>22</sup> Conversely, the band gap can be reduced by lattice contraction without octahedral tilting, when  $\text{Cs}^+$  partially replaces  $\text{FA}^+$  in  $\text{FASnI}_3$ , whereby the absorption is extended up to the NIR region (1040 nm). As the number of inorganic octahedral layer ( $n$ ) increases, the QW barrier is reduced, leading to a contraction of the band gap, regardless of whether the perovskite is in a single crystal or NC/NPL form (Fig. 2a). In the layered halide perovskites such as  $(\text{HA})_2(\text{A})\text{Pb}_2\text{I}_7$  (HA:  $n$ -hexylammonium cation), the band edge and band gap can be tuned by varying the A-site cation with  $\text{Cs}^+$ ,  $\text{MA}^+$ ,  $\text{FA}^+$ ,  $\text{EA}^+$ ,  $\text{GA}^+$ , or  $\text{AA}^+$  (EA: ethyl ammonium, GA: guanidinium, AA: acetamidinium).<sup>21</sup> In addition, a variation in the halide ion, B-site cation, and nature of the spacer molecule helps in altering the band gap.<sup>11,23,24</sup>

### Dielectric constant

When a material is exposed to a static electric field, its long-range charge distribution is significantly influenced by both

the coulombic attraction between opposite charge centers, and the electric polarization field ( $P$ ) within the material, where  $P = \chi_e \epsilon_0 E_0$  ( $\epsilon_0$ : vacuum dielectric constant,  $\chi_e$ : electric susceptibility,  $E_0$ : vacuum electric field).<sup>25</sup> The relative permittivity, or relative dielectric constant ( $\epsilon_r$ ) is a measure of the degree of polarization in bulk dielectrics, and is expressed as  $\epsilon_r = 1 + \chi_e$ . In halide perovskites, the excitons are bound by coulombic force,  $F = -e^2/4\pi\epsilon_0\epsilon_r r^2$  where,  $e$ : electronic charge, and  $r$ : distance between electrons and holes. The dielectric confinement is strongly connected to the band gap,  $E_b$ , and the carrier mobility. In 3D perovskites with a high dielectric constant, the efficient screening of coulombic attraction between excitonic pairs leads to electrons and holes being loosely coupled in all dimensions, resulting in a reduction of  $E_b$ . In contrast to 3D systems, the layered halide perovskites display a periodic gradience in  $\epsilon$ , alternating between the organic and inorganic layers, where  $\epsilon_{\text{inorganic}} > \epsilon_{\text{organic}}$ . In layered halide perovskites, the coulombic attraction of confined excitons within the reduced inorganic well is intensified. This effect is further influenced by the screening effect of the organic barrier, which also increases the  $E_b$ .

In RP  $(\text{I-C}_6\text{H}_{12}\text{NH}_3)_2\text{PbI}_4$ ,  $E_b$  was actually reduced when the  $\epsilon$  value of the spacer molecule was increased from 3.7 to 11.1.<sup>26</sup> This increase was achieved by the molecular intercalation of  $\text{I}_2$ , which forms stable  $\text{I}_2 \cdots \text{I}^-$  interactions, and leads to the formation of  $(\text{I-C}_6)_2[\text{PbI}_4] \cdot 2\text{I}_2$  structures within the organic layers. An elevated gradience in the  $\epsilon$  values between the well and barrier, along with an extension in the chain length of the organic spacer cation, serves to augment the dielectric confinement (Fig. 2b).<sup>25,27</sup> Consequently, these factors exert influence over the  $E_b$  values. The lower dimensional perovskites/hybrid halides (0D, 1D) typically display higher  $E_b$ , which is advantageous for PL properties but unfavourable for optoelectronic devices. Additionally, the enhancement of exciton dissociation and charge transport is facilitated by a higher  $\epsilon$ , which is achieved by factors such as a greater conjugation in the organic spacer cations, extensive  $\pi$ - $\pi$  stacking, the presence of donor-acceptor type organic spacers, and the involvement of charge transfer complexes.<sup>28</sup>

### Effective mass

In a crystal, an electron or exciton interacts with the lattice potential, resulting in a response to external forces distinct from that of a free electron in free space. The effective mass thus characterizes the physical weight of a quantum particle, and its velocity under a given potential. Notably, the effective mass of an exciton is closely tied to the carrier mobility ( $\mu$ ) within the lattice, as expressed by  $\mu = e\tau/m^*$  where  $\tau$  represents the charge carrier scattering time, and  $m^*$  denotes the effective mass of electrons or holes. The optoelectronic performance of any photoactive material is dictated by a high charge carrier mobility, a characteristic facilitated by a small  $m^*$  (e, h). In addition to the optical absorption, the nature of the VB and CB, govern the effective mass, where a greater band curvature in the vicinity of the Fermi energy results in a smaller  $m^*$ .<sup>29</sup>

In hybrid perovskites, the moderate band gap with significant optical absorption, and the smaller  $m^*$  (e, h) are dictated by



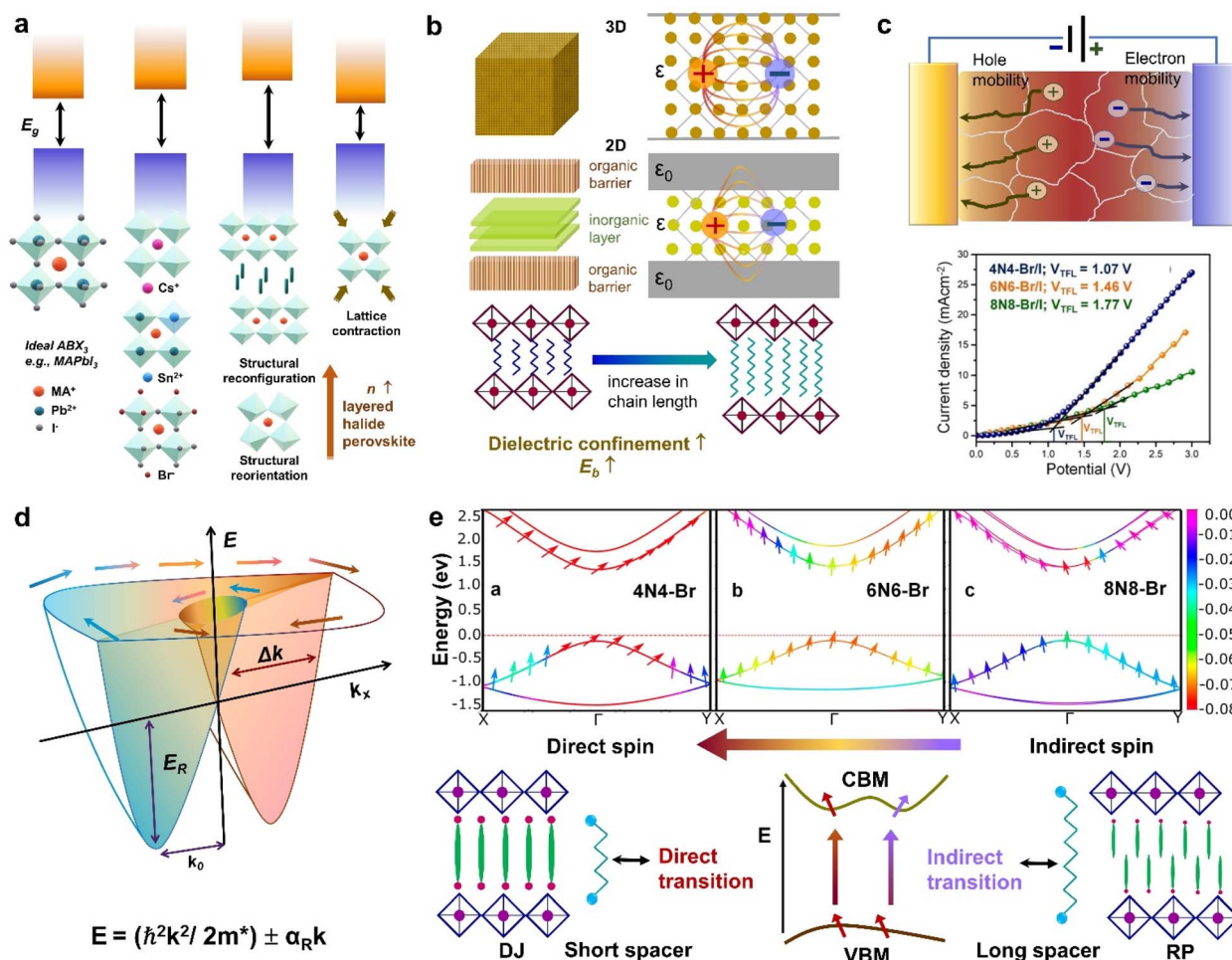


Fig. 2 Schematic representations of the optoelectronic descriptors of 2D halide perovskites. (a) Variation of band gap with change in A, B, X sites; structural rearrangement *via* ligand or metal engineering; octahedral tilting; lattice contraction and variation of  $n$  value. (b) Variation of dielectric constant from 3D to 2D layered structure, and changes in spacer layer thickness. (c) Carrier mobility through a polycrystalline film in the photodetector device (top), and dark current–voltage curve by SCLC measurement, where the calculated trap-state voltage ( $V_{\text{TFL}}$ ) is directly related to the hole mobility ( $\mu$ ).<sup>23</sup> (d) Rashba splitting, dictated by the strength of the Rashba SOC (RSOC) in the system:  $\alpha_{\text{R}}$ , and the energy splitting of the sub-bands:  $\Delta k_{\text{R}} = 2\alpha_{\text{R}}m^*/\hbar^2$ . (e) Variation of spin texture with the spacer layer thickness in DJ ( $x\text{N}x$ ) $\text{SnBr}_4$  ( $x = 8\text{N}8, 6\text{N}6, 4\text{N}4$ ). The  $z$ -component of the spin (colour bar on the right) is associated with the highest occupied band, and the lowest unoccupied band along the  $X-\Gamma-Y$  symmetry direction (top).<sup>23</sup> Dependence of the direct or indirect transition probability on the spin texture including the spacer layer thickness and nature of ammonium cation (RP vs. DJ) (bottom). Reproduced with permission from ref. 23, copyright (2023) American Chemical Society of Chemistry.

the B–X bond. The B–X bond consists of the p-electron shared between the atoms giving rise to a partially filled  $\sigma$  bond and an enhanced optical absorption. The relative electron transfer from the B to X atoms is influenced by the overlap of the adjacent atomic orbitals, and octahedral distortions. A decreasing trend of  $m_e^*$  is observed with a decreasing band gap, and this trend is further influenced by the replacement of halides following the order  $\text{I} < \text{Br} < \text{Cl} < \text{F}$ . The  $m^*$  (e, h) is expected to be higher for the layered halide perovskites, than their 3D counterparts. However, Landau level spectroscopy has revealed that the reduced effective mass ( $\mu$ ) of the layered halide perovskites to be smaller than that of the 3D systems.<sup>30</sup> For instance, while the reduced mass values of  $\text{FASnI}_3$  and  $\text{FAPbI}_3$  are 0.102, and 0.09, those of  $(\text{PEA})_2\text{SnI}_4$ , and  $(\text{PEA})_2\text{PbI}_4$  are found to be 0.055, and 0.091, respectively. This reduction in effective mass for Sn-

based 2D hybrid halides is attributed to a favourable alignment of I p-orbitals with the  $5s^2$  lone pair of Sn, strengthening hybridization at the VB edge.<sup>30</sup>

### Carrier mobility

Carrier mobility determines the speed at which electrons or holes can move through a crystal lattice when subjected to an electric field. The ability of charge carriers to move in response to an applied electric field is crucial in various fields, particularly in photovoltaics and optoelectronics (Fig. 2c). Carrier mobility is investigated either through a combination of electrical probes, such as space charge limited current (SCLC), time of flight, Hall measurement, or by an optical probe such as transient absorption spectroscopy, time-resolved microwave conductivity, *etc.* Essentially, longer spacer chains may hinder



the efficient movement of charge carriers within the perovskite structure, leading to reduced mobility. We have observed that the mobility in DJ Sn(II) hybrid halide perovskites decreases as the unconjugated spacer chain length increases from 4 to 8 carbons.<sup>23</sup> In layered halide perovskites, the movement and dynamics of charge carriers are governed by  $\epsilon$ , and the insulating barrier created by the organic spacer cations. Reducing the spacer layer thickness typically leads to enhanced carrier mobility, and a decrease in trap state density (Fig. 2c). In SCLC measurements, the carrier mobility is influenced by factors such as the thickness and crystallinity of the polycrystalline film, as well as the quality of the single crystals. The evaluation of these parameters involves the fabrication of the electron-only, or hole-only devices. The Mott-Gurney's equation is then applied, and carrier mobility is calculated from the slope of the current density vs. square of the voltage curve.<sup>23</sup>

### Rashba splitting

The Rashba effect, also known as the Bychkov–Rashba effect, refers to a spin–orbit phenomena, leading to a splitting of the spin-degenerate energy bands in low-dimensional materials and semiconductors with asymmetric potentials or surfaces. In the absence of the Rashba effect, electrons exhibit the same spin and momentum, but in its presence, an asymmetry in the electronic environment causes the electrons with different momenta to experience slightly different energies. The difference in energy is accompanied by spin polarization, which induces a helical spin texture of the dispersed energy,  $E(k)$ , according to eqn (1):

$$E = \left( \frac{\hbar^2 k^2}{2m^*} \right) \pm \alpha_R k \quad (1)$$

where,  $\alpha_R$  represents the strength of the Rashba spin–orbit coupling (SOC) in a particular system (Fig. 2d).<sup>31–33</sup> The coupling between electric field, and the spin degrees of freedom is the basis of engineering the spintronic devices such as spin transistors, spin valves, and spin-based memory devices.<sup>34</sup> The Rashba effect can affect the carrier recombination pathways, through the creation of an indirect band gap whose magnitude depends on SOC, and the degree of symmetry breaking.

In halide perovskites, the local electric fields induced by the ionic defects, give rise to the inversion symmetry breaking, and Rashba-splitting. The phase transitions, and motional freedom of A-site cations can result in a local breakdown of the inversion symmetry which in turn alters the local electric field, escalating the band splitting. While Rashba splitting has minimal effect on the carrier recombination of 3D perovskites, the reduced dimension of the layered halide perovskites has a strong impact on the SOC, making Rashba effect more prominent.<sup>35</sup> When the organic spacer cations are randomly oriented, the layered halide perovskites display a lower symmetry caused by the BX<sub>6</sub> octahedral tilting, which triggers the band splitting in the CB and VB extrema.<sup>36</sup> In some cases, the Rashba effect depends on the number of octahedral layers ( $n$ ) in the inorganic block. A particular  $n$  value can either maintain the centrosymmetric crystal structure, showing an absence of Rashba effect, or it can

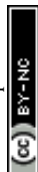
lead to a broken symmetry leading to band splitting.<sup>37</sup> The correlation between symmetry breaking, and the Rashba effect is commonly understood from techniques such as two-photon absorption spectroscopy, and angle-resolved photoelectron spectroscopy,<sup>38</sup> beside other transient and steady-state measurements.<sup>39–41</sup>

### Transition probability and spin texture

In semiconductors with a direct band gap, the optical transitions are governed by the direct transitions in  $k$ -space from the  $\Gamma$ -point of the Brillouin zone. Hence, the optoelectronic performance is guided by the band gap, the effective mass, or the band dispersion. Apart from the common descriptors, the spin–orbit interactions can alter the orientation of the electron spins at the states associated with the CBM, and VBM.<sup>23</sup> Even if the spins remain direct in momentum space, the change in electron spin orientation can result in a mixture of direct and indirect optical transitions (Fig. 2e). In the context of optical transitions between the VBM and CBM, the transition probability can be determined by examining the spatial part of the wave function. The square of the expectation value of the dipole operator, when flanked between the wave functions corresponding to the VBM and CBM, provides information about the likelihood or probability of an electron making a direct or indirect transition from the VBM to CBM. In layered halide perovskites, the organic spacer molecule can regulate the admixture of the p-orbitals in the B-site cation of the inorganic block, which can lead to different spin textures at the VBM and CBM (Fig. 2e).<sup>23</sup> Treating the electron spin classically as a vector quantity, the direct and indirect components are calculated by considering the “parallel” and “perpendicular” spins, respectively. In the absence of Rashba splitting, the spin texture argument is particularly useful in dictating the trends of optoelectronic performance of the layered halide perovskites with a library of organic spacer molecules. The manipulation of spin texture in materials, particularly in the absence of a magnetic field or ferromagnetic components, is crucial for various spin-dependent phenomena and applications in the field of spintronics.

## Low-dimensional hybrid halides/perovskites

Before delving into the discussion on lead-free layered halide perovskites, it is worth exploring low-dimensional hybrid halides, which encompass structures ranging from 0D to 2D. These hybrid halides are distinct from 2D layered halide perovskite structures. The class of hybrid halides captivates the scientists for their potential to exhibit unique optical, and optoelectronic properties, and therefore find broad applications across various fields such as sensing, LED, laser, X-ray detection, ferromagnetism, and ferroelectricity, *etc.* Lead-free metal centers with charges of +1 or +3, as well as the transition metals, often exhibit such structures. For further discussion, we have selected three distinct metal centers, Bi(III), Cu(I), and Mn(II), due to their unique and diverse optoelectronic properties,



offering insight into this evolving area. These p and d-block elements often exhibit both contrasting and parallel phenomena in their optoelectronic properties. For p-block elements such as,  $\text{Bi}^{3+}$ ,  $\text{Sb}^{3+}$  the inorganic slabs typically exist in an isolated and confined state, separated by organic spacer cations. This arrangement enhances the electron-phonon coupling, leading to a phenomenon known as self-trapped excitonic (STE) emission. The photoluminescence (PL) band originating from the transition metal centers is influenced by multiple electronic states, Jahn-Teller (J-T) distortion, and STE emission, contributing to the complex spectral characteristics observed in these materials. Moreover, these environmentally benign, earth-abundant metal hybrid halides/perovskites demonstrate high structural stability in the ambient atmospheric conditions. Therefore, recognizing its significance, we have presented a concise overview of the structural and optoelectronic properties of low-dimensional hybrid perovskites/halides to facilitate a comparative analysis with the layered halide perovskites.

Endowed with unique structural chemistry along with the optical and electronic features, the low-dimensional perovskites having a lead-free B-site metal center (*e.g.*, Sn, Bi, Sb, In, Cu, Mn, *etc.*) are rapidly evolving.<sup>9,42-44</sup> Although,  $\text{Bi}^{3+}$  is isoelectronic to  $\text{Pb}^{2+}$ , its iodide version often renders the formation of vacancy-ordered perovskites because of the lack of extended connectivity between the Bi-I units. The organic cation-induced quantum barrier results in a wider optical band gap for Bi-containing perovskites, compared to their Pb-counterparts. The varying Bi-I connections, *e.g.*,  $\text{Bi}_2\text{I}_9^{3-}$  (face sharing),  $\text{BiI}_4^-$  (edge sharing) and  $\text{BiI}_5^{2-}$  (corner-sharing) also result in the isolated 0D, or quasi-2D structures.<sup>45</sup> The introduction of conjugated spacer cations can trigger the organic-inorganic coupling, which can augment the charge transfer and photoconductivity, in the systems such as, (naphthalene diimide bis(ethylammonium))<sub>2</sub> $\text{BiI}_7$ , and (naphthalimide ethylammonium)<sub>2</sub> $\text{BiI}_5$ .<sup>46-51</sup> Other p-block elements, such as Sb, and In, are also known to form low-dimensional hybrid halides.<sup>43,44</sup>

Apart from the p-block elements, the hybrid transition metal-halides are recognised due to their outstanding emission properties, along with their magnetic, ferroelectric, thermochromic, photochromic, X-ray detection, anti-counterfeiting, X-ray scintillation, and spintronic functionalities.<sup>42</sup> One of the widely investigated potential candidates is the class of Cu based hybrid halide. Cu is known to exist in tetrahedral, octahedral, trigonal planar, and linear coordination environments. Although the Cu(I) systems prefer tetrahedral coordination, they can show isolated linear connectivity, *e.g.*  $(\text{PH}_4\text{P})^+\text{CuX}_2$  ( $\text{X} = \text{Cl}, \text{Br}$ ), and exist as either 0D or 1D structures. Cu(I) can also form a layered structure, such as  $(\text{tBA})_3\text{Cu}_6\text{I}_9$  ( $\text{tBA} = \text{tert-butyl ammonium ion}$ ), where corner-shared  $[\text{Cu}_6\text{I}_9]^{3-}$  structural units are formed by common edge-sharing of six  $\text{CuI}_4$  tetrahedral units. Overall, Cu(I) halides feature linear  $[\text{CuX}_2]$ , tetrahedral  $[\text{CuX}_4]$ , trigonal planar  $[\text{CuX}_3]$  building blocks and a series of polyanionic clusters of cuprous systems such as  $\text{RCuX}_2$ , or  $\text{R}_2\text{Cu}_4\text{X}_6$  ( $\text{R} = \text{organic cations}$ ).<sup>52</sup> Besides the excellent Cu-based hybrid halide emitters, there are a few non-luminescent Cu-

based hybrid halides, namely,  $\text{PyCs}_3\text{Cu}_2\text{Br}_6$ , and  $(\text{PH}_4\text{P})^+\text{CuX}_2$ , where the organic cations have a detrimental impact on the PL quantum yield (PLQY). On the other hand, the layered  $\text{C}_6\text{H}_{10}\text{N}_2[\text{CuCl}_4]$  has been proven to be a promising photoabsorber.

In the Mn(II) halide category,  $\text{Mn}^{2+}$  displays red and green emission depending on the strong-field octahedral, and weak-field tetrahedral coordination environments, respectively. In the hexacoordinated systems, one  $\text{Mn}^{2+}$  and six  $\text{X}^-$  ions combine to form the point, edge or face sharing  $[\text{MnX}_6]^{4-}$  octahedra which are classified into 0D, 1D, and 2D hybrid halides.<sup>53</sup> The  $[\text{MnX}_4]^{2-}$  tetrahedra, initially exhibiting green emission, can undergo changes in its chemical environment through tetrahedral tilting, or by an external stimulus such as pressure, resulting in a shift from green to yellow, orange, and red emission. Mn(II) hybrid halides have high PLQY which is beneficial for commercial LEDs and WLED chips. The octahedrally coordinated red emitting  $(\text{C}_4\text{H}_{12}\text{N})\text{MnCl}_3$ ,  $(\text{CH}_6\text{N}_3)_2\text{MnBr}_4$  and tetrahedrally coordinated  $((\text{C}_8\text{H}_{20}\text{N})_2\text{MnBr}_4)$ ,  $(\text{C}_8\text{H}_{34}\text{P}_2)\text{MnBr}_4$  achieve 91.8%, 61.9% and 81.5%, 95% PLQY, respectively. The absorbance or PL excitation (PLE) spectra are mainly attributed to the multiple electronic transitions, from the  ${}^6\text{A}_1(\text{S})$  ground state to the  ${}^4\text{A}_2(\text{F})$ ,  ${}^4\text{T}_1(\text{F})$ ,  ${}^4\text{T}_1(\text{P})$ ,  ${}^4\text{E}(\text{D})$ ,  ${}^4\text{A}_1$ ,  ${}^4\text{E}(\text{G})$ ,  ${}^4\text{T}_2(\text{G})$ , and  ${}^4\text{T}_1(\text{G})$  excited states.<sup>53</sup> The  ${}^4\text{T}_1 \rightarrow {}^6\text{A}_1$  transition is responsible for the bright emission of these systems. When the  $\text{Mn}^{2+}$ -halide polyhedral units are surrounded by non-conjugated or less conjugated organic cations, it results in a type-I band alignment. In case of the conjugated systems, the lowest unoccupied molecular orbital (LUMO) is too low for a type-I alignment, which in turn results in PL quenching.

When water molecules are present in the lattice of the lead-free hybrid structures *e.g.*,  $(\text{propanediammonium})_2\text{Bi}_2\text{I}_{10} \cdot 2\text{H}_2\text{O}$ , and  $(\text{t-BA})_2\text{Cu}_2\text{I}_4 \cdot \text{H}_2\text{O}$ , the interaction between the inorganic block, and spacer cation is weakened by the hydrogen bonding with the organic cation.<sup>54</sup> This in turn alters the chemical environment which affects the optoelectronic properties. Recently, macromolecules, or crown ether caged metal polyhedral halides have become a potential alternative of traditional hybrid perovskites because of their high PLQY, and ambient stability.

## Sn-based layered halide perovskites

Sn-based 2D hybrid perovskites frequently exhibit a  $\langle 100 \rangle$  orientation, and are considered among the most promising lead-free alternatives in the p-block. In the presence of  $\text{GA}^+$  with  $\text{MA}^+$  or  $\text{Cs}^+$  cations, the Pb-based hybrid halide adapts the ACI phase having  $\langle 110 \rangle$  orientation.<sup>15</sup> The  $\langle 110 \rangle$  oriented structure was obtained for  $[\text{NH}_2\text{C}(\text{i})=\text{NH}_2]_2(\text{CH}_3\text{NH}_3)_m\text{Sn}_{m-1}^{1-3m+2}$  ( $m = 2-4$ ),  $(\text{C}(\text{NH}_2)_3)_2\text{SnI}_4$ ,  $\alpha\text{-(NH}_3\text{C}_5\text{H}_{10}\text{NH}_3)\text{SnI}_4\alpha\text{-(HA)SnI}_4$  ( $\text{HA} = \text{histammonium}$ ), and with 1,3 propane diammonium cation having the bromide counterpart.<sup>55</sup> Sn-halide perovskite single crystals are conventionally synthesized by the acid precipitation method at a slightly elevated temperature, where the precursors (metal salts, and amines, or pre-prepared amine-salts) are taken in a specific molar ratio, dissolved in an adequate amount of acid (HI, HBr, HCl), commensurate with the halide composition. The single crystals are obtained by slow cooling of the



solution. The single crystals can also be generated by the anti-solvent method, or slow evaporation over extended periods.

Given that the standard reduction potential for the  $\text{Sn}^{4+}/\text{Sn}^{2+}$  couple is only +0.15 V,  $\text{Sn}^{2+}$  tends to be oxidized to  $\text{Sn}^{4+}$  under standard conditions. To restrict the oxidation of  $\text{Sn}^{2+}$  to  $\text{Sn}^{4+}$  state, excess  $\text{H}_3\text{PO}_2$ , and  $\text{SnF}_2$  (as an additive) are employed in the acid precipitation method. Notably, for the Sn-based 2D halide perovskites, discussed in this perspective, the presence of  $\text{Sn}(\text{iv})$  is negligible compared to  $\text{Sn}(\text{ii})$ . The quantification of  $\text{Sn}(\text{iv})$  was achieved by analysing the area under X-ray Photoelectron Spectroscopy (XPS) plots. Specifically, in Sn-containing layered halide perovskites with mixed halide compositions (such as 8N8-Br/I, 6N6-Br/I, and 4N4-Br/I),  $\text{Sn}(\text{iv})$  is absent in the XPS plots of Sn 3d level. However, in pure iodide samples (e.g., 8N8-I), a small proportion of  $\text{Sn}(\text{iv})$  was detected, with a calculated fraction of  $\text{Sn}(\text{iv})$  as 0.03. Furthermore, the superlattice nanostructures also did not exhibit the  $\text{Sn}(\text{iv})$  state in XPS analyses.

### Optical properties

The optical properties of Sn-based layered halide perovskites are governed by the halide composition, the type of organic spacer cation, spacer layer thickness, molecular intercalation, and the electron–phonon coupling that leads to the formation of STE states. The RP or DJ Sn-based bromide systems usually show the optical absorption below 450 nm, and a broad intense emission with large Stokes shift at room temperature.<sup>9</sup> The DJ perovskite with the 1,8-diammonium octane (8N8) spacer, experiences a blue shift of the absorption onset with a reduced optical density as the band gap is enhanced from the iodide to the mixed halide, and the bromide counterparts (Fig. 3a).<sup>23</sup> The PL emission band is also blue shifted from iodide to bromide (Fig. 3b). The emission band positions are independent of the excitation wavelength ( $\lambda_{\text{ex}}$ ), although the PL intensity is enhanced at lower  $\lambda_{\text{ex}}$ . The DJ perovskites has an inherent structural stability in having the hydrogen bonding in between the divalent spacer molecule, and the  $\text{SnX}_6$  octahedra. On the contrary, the RP counterpart consists of an insulating gap between the protonated *n*-octylammonium (8N) spacer cation held together by van der Waals interaction, which in turn deteriorates their optoelectronic performance. Both DJ (8N8)  $\text{SnBr}_4$  (8N8-Br), and RP  $(8\text{N})_2\text{SnBr}_4$  (8N-Br) have appreciable PLQY of  $99.7 \pm 0.3\%$ , and  $91.7 \pm 0.6\%$ , respectively. While the 8N8-DJ retains the PLQY even after one month storage under ambient conditions, the PLQY of 8N8-RP continuously drops with time (Fig. 3c and d). The stronger H-bonding interactions and absence of van der Waals gap offer greater stability for the DJ perovskites compared to the RP counterpart.<sup>56</sup> Reducing the spacer layer thickness through the use of 1,6-diammonium hexane (6N6) and 1,4-diammonium butane (4N4) spacers maintains a comparable absorption onset, indicating a proximity in their band gaps. However, noteworthy alterations are observed in the optical density, as illustrated in Fig. 3e, accompanied by changes in the emission profile. 4N4-DJ shows a narrow band edge (BE) emission with low Stokes shift, whereas for 6N6-DJ and 8N8-DJ, the emission band is broadened due to the STE emission (Fig. 3f).

The structural conformation and optical properties of the  $\text{Sn}(\text{ii})$  layered iodide perovskites can also be tuned by the reversible molecular intercalation–deintercalation with the spacer cations.<sup>57,58</sup> The intercalation of benzene ( $\text{C}_6\text{H}_6$ ) is possible in 2,3,4,5,6- pentafluorophenethylammonium bilayers to form the  $(\text{C}_6\text{F}_5\text{C}_2\text{H}_4\text{-NH}_3)_2\text{SnI}_4 \cdot (\text{C}_6\text{H}_6)$  crystal.<sup>57</sup> Conversely, fluorinated benzene ( $\text{C}_6\text{F}_6$ ) can be inserted in between the phenethylammonium bilayers forming  $(\text{C}_6\text{H}_5\text{C}_2\text{H}_4\text{NH}_3)_2\text{-SnI}_4 \cdot (\text{C}_6\text{F}_6)$ . Also, the intercalation and deintercalation of molecular  $\text{I}_2$  in  $(\text{A})_2\text{PbI}_4$  is reduced with increasing spacer chain length of the  $\text{A}^+$  cation.<sup>58</sup> Here, the  $\text{I}_2$  intercalated crystal shows two absorbance and emission peaks whereas, the pristine crystals display only one peak in the absorbance and emission profiles. Such a phenomenon has significant impact on the photochromism, sensing, and conductivity of the devices.

### STE emission

At a specific excitation power, a stable equilibrium in the population density of bound, free, and trapped excitons is established prior to their radiative relaxation. The density of these charge carriers is contingent upon factors such as the rate of photocarrier generation, the lifetimes within their respective states, and the intensity of excitation.<sup>59</sup> STE emission involves the transfer of charge carriers from the CBM to these overlapped states, and subsequent emission to the  $^1\text{S}_0$  ground state. The luminescence of layered halide perovskites mostly originates from the defect scattering, and optical phonon scattering, except for the BE emission. The scattering processes involving the electrons, optical and acoustic phonons contribute to the attainment of thermal equilibrium, which in turn influences the electronic band structure, and leads to modifications in the PL spectra. These scattering processes are responsible for the thermal variation of the full-width at half-maximum (FWHM) of the PL bands.

One of the conventional methods for analysing the electron–phonon coupling is to evaluate the FWHM of temperature-dependent PL spectra, according to eqn (2):<sup>9</sup>

$$\text{FWHM}(T) = 2.36\sqrt{S}\hbar\omega_{\text{ph}}\sqrt{\coth\left(\frac{\hbar\omega_{\text{ph}}}{2k_{\text{B}}T}\right)} \quad (2)$$

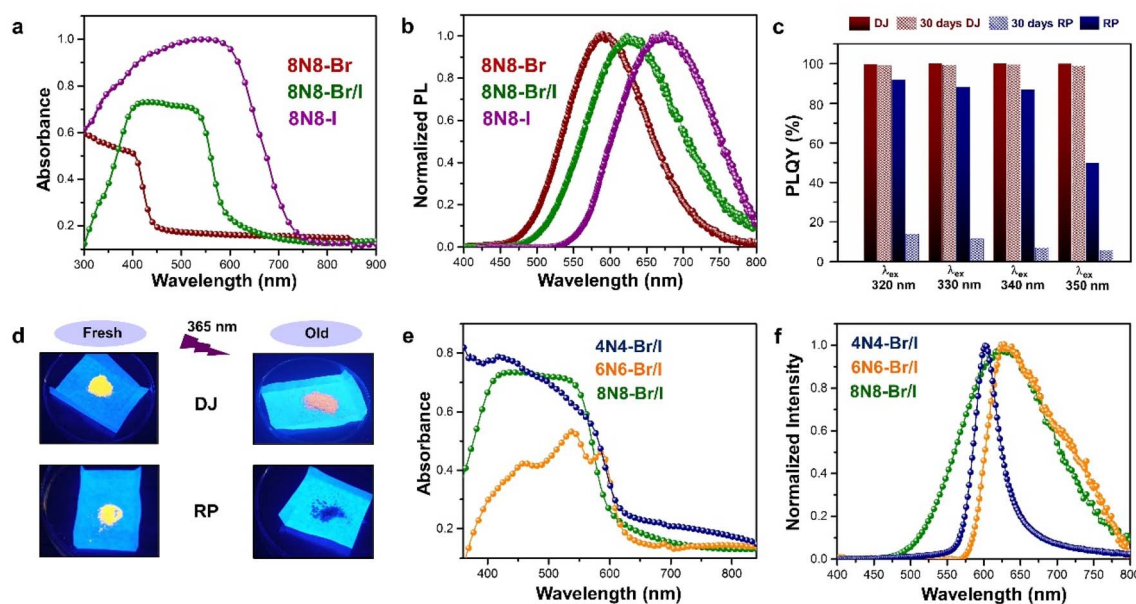
where  $\hbar\omega_{\text{ph}}$  is the phonon energy,  $k_{\text{B}}$  is Boltzmann constant,  $S$  is electron–phonon coupling parameter (Huang–Rhys factor). The contribution of different phonon components can be described by fitting the FWHM vs.  $1/T$  plots, according to eqn (3):

$$\begin{aligned} \Gamma(T) &= \Gamma(0) + \Gamma_{\text{ac}} + \Gamma_{\text{LO}} = \Gamma(0) + \gamma_{\text{ac}}T + \gamma_{\text{LO}}n(T) \\ &= \Gamma(0) + \gamma_{\text{ac}}T + \frac{\gamma_{\text{LO}}}{\exp\left[\frac{E_{\text{LO}}}{k_{\text{B}}T}\right] - 1} \end{aligned} \quad (3)$$

where the FWHM at temperature  $T$  and 0 K, respectively, are denoted by  $\Gamma(T)$  and  $\Gamma(0)$ ; the longitudinal optical (LO) and acoustic phonon modes are  $\Gamma_{\text{ac}}$  and  $\Gamma_{\text{LO}}$ , respectively;  $\gamma_{\text{ac}}$ ,  $\gamma_{\text{LO}}$  and  $E_{\text{LO}}$  are the exciton–acoustic phonon coupling strength, exciton–LO phonon coupling coefficient, and the characteristic LO phonon energy, respectively. A higher value of  $\gamma_{\text{LO}}$  signifies a stronger coupling between carriers and phonons, particularly







**Fig. 3** (a) UV-vis absorption, and (b) PL spectra of  $(8N8)SnX_4$  ( $X = Br^-$  and/or  $I^-$ ).<sup>23</sup> (c) Bar plots showing the ambient-stability of PLQY between the fresh and 30 days stored DJ  $(8N8)SnBr_4$  and RP  $(8N)_2SnBr_4$  samples under relative humidity of 55% and 25 °C, at different  $\lambda_{ex}$ .<sup>9</sup> (d) Digital images of the corresponding DJ  $(8N8)SnBr_4$  and RP  $(8N)_2SnBr_4$  crystals showing better ambient stability of the DJ perovskite.<sup>9</sup> (e) UV-vis absorption and (f) PL spectra at  $\lambda_{ex} = 360$  nm for  $xNx-Br/I$  ( $x = 8N8, 6N6, 4N4$ ) Sn-mixed halide DJ perovskites.<sup>23</sup> Reproduced with permission from ref. 9 and 23, copyright (2022 & 2023) American Chemical Society of Chemistry.

evident at lower  $\lambda_{ex}$ , resembling the behaviour observed in the Huang–Rhys factor. The elevated values of  $S$ ,  $\gamma_{LO}$  and  $E_{LO}$  indicate an enhanced electron–phonon coupling, conducive to the occurrence of STE emission. Typically, systems with  $S$  values exceeding 10 demonstrate significant electron–phonon coupling, thus manifesting broad STE peaks.<sup>60</sup> In the case of the layered bromide perovskite  $(8N8-SnBr_4)$  discussed in this perspective, notably high  $S$  values of 28.5 and 27.4 are observed at different excitation wavelengths (Fig. 3d), resulting in the broad and intense STE emission peaks (Fig. 3a and b). Conversely, the  $CsPbX_3$  NCs, which exhibit only fundamental emission (FE) without STE, demonstrate very low  $S$  values ( $<1$ ).

The overlapped delocalised states below the CBM, and the corresponding STE emission are responsible for the higher PLQY of  $8N8-Sn$  (RP/DJ).<sup>9</sup> With a  $\lambda_{ex}$  of 380 nm, the intensity of the yellow STE emission band at 580 nm increases with increasing temperature. Below 100 K, the 440 nm BE emission is observed (Fig. 4a). This BE is both spin and parity allowed, and occurs from the  $^1P_1$  excited state to  $^1S_0$  ground state which is common for the B-site cations with  $ns^2$  configuration. At temperatures below 100 K, where excited electrons possess lower thermal energy, the carrier–phonon coupling becomes less influential, leading to a reduced intensity of the STE band compared to the BE emission. As the temperature rises, the excited electrons gain thermal energy, enabling them to surpass the activation energy for transport from CBM to the STE state. The dominance of the STE band over the BE emission occurs at  $\lambda_{ex} < 380$  nm, while at higher  $\lambda_{ex}$ , only the BE emission band is observed (Fig. 4b). Regardless of temperature, the STE emission

is more prominent at lower  $\lambda_{ex}$ , since the electrons can be excited to higher vibrational energy states, facilitating their transfer to the delocalized STE states, making the STE emission more favourable. The position of the BE emission peak remains temperature-independent at each  $\lambda_{ex}$ . However, the STE emission experiences a blue shift between 5 and 75 K, followed by a red shift up to 300 K. This variation in the STE peak position is attributed to the interplay of competing effects of thermal expansion, and electron–phonon interactions. At  $\lambda_{ex}$  of 360, 380, and 400 nm, the calculated  $E_b$  values are  $34.7 \pm 1.2$ ,  $35.0 \pm 0.8$  and  $37.3 \pm 1.5$  meV, respectively. The fact that the  $E_b$  values are independent of  $\lambda_{ex}$ , suggesting a favourable electronic transition from the free exciton state (FE) to the free carrier state (FC). This characteristic is crucial for a facile electron extraction process.

### Structural impact on STE emission

The selection of the organic spacer cation induces variations in the parameters such as  $E_b$ , dielectric constant ( $\epsilon$ ), and the electronic band structure. Transitioning from the aromatic to aliphatic monoammonium cations, and with an increase in the organic spacer layer thickness, the band gap increases.<sup>59</sup> The aromatic ammonium cations forestall the thermal movement between the inorganic octahedral layers due to the strong CH– $\pi$  stacking of the aromatic rings. Nevertheless, the presence of alkyl chains induces varying degrees of distortion in the inorganic octahedra, leading to alterations in the density of defect states. This, in turn, promotes electron–phonon coupling within the system through structural distortions, lattice vibrations, and thermal movement between the inorganic layers. The



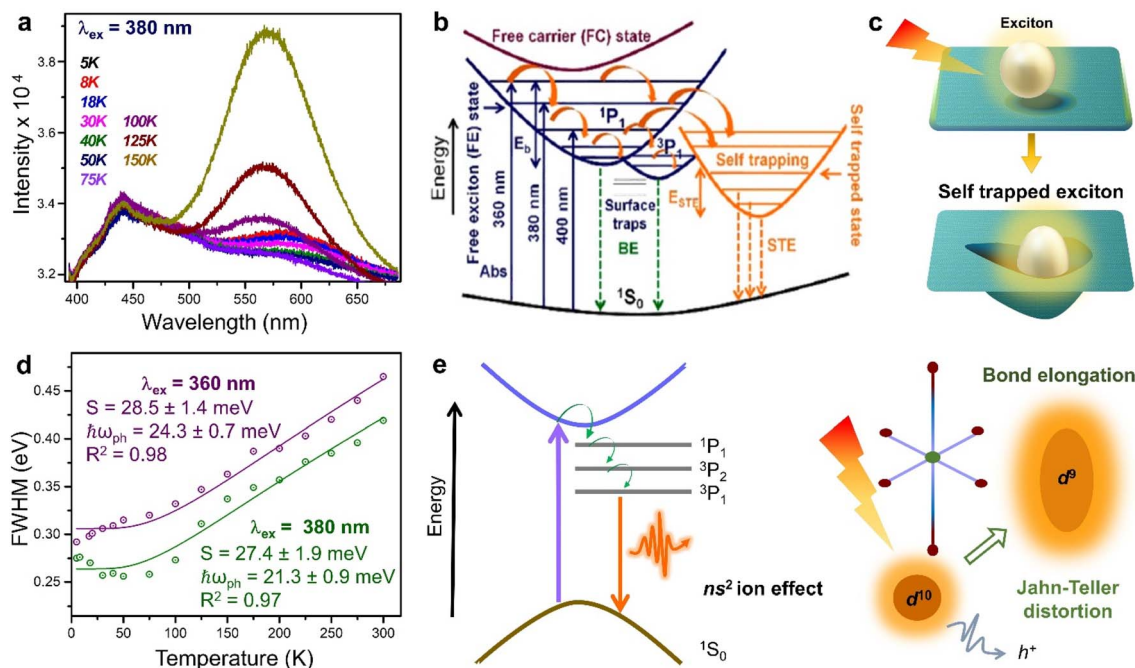


Fig. 4 (a) PL spectra of (8N8)SnBr<sub>4</sub> in the range 5 to 150 K, at  $\lambda_{\text{ex}} = 380$  nm.<sup>9</sup> Schematics of (b) the energy level diagram demonstrating the BE and STE emission,<sup>9</sup> and (c) the exciton self-trapping in the perovskite lattice. (d) FWHM (in eV) as a function of temperature at  $\lambda_{\text{ex}}$  of 360 and 380 nm for (8N8)SnBr<sub>4</sub>.<sup>9</sup> (e) Schematics showing the broad emission through the sub-band gap states, which are present in a system with stereochemically active  $ns^2$  lone pairs, along with a parallel phenomenon of J–T distortion, together promoting the STE. Reproduced with permission from ref. 9, copyright (2022) American Chemical Society of Chemistry.

scattering effect due to the charged defect states is prominent in reducing the PLQY of (PEA)<sub>2</sub>SnI<sub>4</sub>, (BA)<sub>2</sub>SnI<sub>4</sub>, (HA)<sub>2</sub>SnI<sub>4</sub>, and (OA)<sub>2</sub>SnI<sub>4</sub> [PEA: ph, BA: butylammonium cation, HA: hexylammonium cation, OA: octylammonium cation].<sup>59</sup> Elliot's theory provides substantial qualitative information on the  $E_b$ , and  $\epsilon_A$  values of organic cations which further shows that the  $\epsilon_A$  for an aromatic spacer is smaller than the alkyl ammonium cation.<sup>59,61,62</sup> Furthermore in layered halide perovskites, a strong coulombic interaction between the bound excitons is responsible for the lesser value of  $\epsilon_A$  (A: spacer) than  $\epsilon_w$  (W: Sn-octahedra). These two factors contribute to the lower  $E_b$  observed in (PEA)<sub>2</sub>SnI<sub>4</sub>, compared to its alkyl spacer counterparts.

A strong correlation exists between the structural factors, and the electron–phonon coupling (Fig. 4c). The rigidity of different structures can be distinguished by extracting the atomic displacement ( $U_{\text{eq}}$ ) in the single crystals. The higher values of  $U_{\text{eq}}$ , and  $I(\text{LO})$  observed in (OA)<sub>2</sub>SnI<sub>4</sub> in comparison to (PEA)<sub>2</sub>SnI<sub>4</sub> indicate a greater contribution of STE emission in the alkyl chain systems.<sup>59,63–66</sup> This is attributed to the defect states, resulting in the intraband PL, and a subsequent loss of PLQY. Since STE depends on the octahedral tilting in the inorganic layer, the PL intensity also increases with higher out-of-plane octahedral tilting. Increasing the chain length of the organic spacer cations also enhances the compressive strain as well as the degree of octahedral distortion (8N8 > 6N6 > 4N4).<sup>9</sup> The highest out-of-plane octahedral distortion increases the electron–phonon coupling. From the fitted FWHM (in eV) as

a function of temperature, the numerical value of  $S$ ,  $\hbar\omega_{\text{ph}}$  are calculated (Fig. 4d).

### Jahn–Teller distortion

A vast majority of the halide perovskites have a reduced crystal structure symmetry due to the lattice distortions, and the J–T distortion leading to octahedral tilting. This leads to the heterotypes, where the overall perovskite framework is preserved like the aristotype, but having a lower symmetry.<sup>67</sup> In particular, the rock-salt-ordered double perovskite structure is stabilized by the J–T distortion, that splits the unequally occupied  $e_g$  orbitals, and lowers the energy of the octahedral units.<sup>68</sup> In contrast to the electronic transition arising from the J–T distortion in Cu(II), with  $d^9$  electronic configuration, there are two possible conditions when the J–T inactive Cu(I) can display the electronic transitions. The first is the temporary oxidation of the  $d^{10}$  system into  $d^9$  configuration by photoexcitation. The second criterion is the relaxation of the Laporte selection rule by mixing the d-orbitals with s- and p-orbitals in the complex hybrid structure. This J–T distortion results in anti-ferrodistortive arrangement in the coordination environment of the inorganic layer. When photoexcitation promotes an electron into Cu-4s orbital leaving a hole in the 3d orbital, the J–T distortion escalates the electron–phonon coupling (Fig. 4e).

The 0D (Ph<sub>4</sub>P)CuX<sub>2</sub> displays STE emission, since the charge is localized within the isolated [CuX<sub>2</sub>]<sup>−</sup> units. On the other hand, the (tBA)CuX<sub>2</sub> (X = Cl, Br) having a similar structural configuration, displays cyan-green emission exhibiting PLQY of



92.8% for X = Cl<sup>-</sup>, and 80.5% for X = Br<sup>-</sup>, while (tBA)CuI<sub>2</sub> is a white light-emitter with a PLQY of 54.3%.<sup>69</sup> In the iodide system, dispersive Cu-4s states contribute strongly to the CBM, and thereby the J-T distortion creates intrinsic self-trapped states, overruling the STE emission.<sup>70</sup> The manganese containing hybrid halides usually contain Mn<sup>2+</sup> centers with d<sup>5</sup> configuration, giving rise to multiple excited electronic states. The green emission originates from <sup>4</sup>T<sub>1</sub> → <sup>6</sup>A<sub>1</sub> transition, and the red emission is due to the ferromagnetic coupling between two neighbouring Mn<sup>2+</sup> ions. When the thermal vibration of the lattice is minimized, the non-radiative trap-state induced transitions are reduced which enhances the PLQY. The PLQY can reach up to 81% for [P14]<sub>2</sub>[MnBr<sub>4</sub>] (P14: *N*-butyl-*N*-methylpyrrolidinium cation).<sup>71</sup> However, the appreciable PLQY in various hybrid halides containing Sn, Cu, Bi, Sb, *etc.*, is attributed primarily to the electron-phonon coupling.

The photo-oxidation-driven, or the J-T distortions generate the intrinsic STE states in transition metal-based systems, while the lattice deformations or vacancies create the extrinsic STE states in p-block systems. Besides the electron-phonon coupling, the electronic contribution of vacant (*n* - 1)<sup>th</sup> d- and *n*th s-orbitals cannot be ignored to decide the nature of emission. In the Sn<sup>2+</sup> perovskites, a stereochemically active ns<sup>2</sup> lone pair creates the dynamic J-T distortion. The ns<sup>2</sup> ions are present as a parent or dopant center, whereas the excited sp state contains lower <sup>3</sup>P state which can either undergo a dynamic J-T distortion, or a strong spin orbit coupling, splitting the sp state into the <sup>3</sup>P<sub>0</sub>, <sup>3</sup>P<sub>1</sub>, and <sup>3</sup>P<sub>2</sub> states. While <sup>1</sup>S<sub>0</sub> → <sup>1</sup>P<sub>1</sub>, and <sup>1</sup>S<sub>0</sub> → <sup>3</sup>P<sub>1</sub> transitions are complete, and partially spin-allowed, respectively, <sup>1</sup>S<sub>0</sub> → <sup>3</sup>P<sub>2</sub>, and <sup>1</sup>S<sub>0</sub> → <sup>3</sup>P<sub>0</sub> are the forbidden transitions. However, the dynamic J-T distortion in <sup>3</sup>P<sub>1</sub> state along with the off-center position in <sup>1</sup>S<sub>0</sub> ground state, result in a broad band <sup>1</sup>S<sub>0</sub> → <sup>3</sup>P<sub>1</sub> emission with large stoke shift (Fig. 4e).<sup>72</sup> Since the dynamic J-T distortion also enhances the electron-phonon coupling, the origin of the transitions can be either STE, or STE-like <sup>3</sup>P<sub>*n*</sub> (*n*=0, 1, 2) → <sup>1</sup>S<sub>0</sub>. The temperature-dependent dynamic charge transfer is also observed in hybrid halide perovskites, and such as charge transfer, or defect scattering is arduous to be distinguished from STE.<sup>73</sup> Although, these phenomena are interconnected, the dominant factor governs the optical properties, depending on the perovskite lattice.

### Polaronic effect

The polaron can be expressed as a quasiparticle resulting from the interaction between an electron (or hole), and the polarizing field in a crystal lattice. The self-trapping of charge carriers is possible when they experience a coulombic interaction with the relatively heavy, and slow-moving atoms. The self-trapped carrier remains bound in the potential well produced by the shift from the equilibrium position of the atoms. This displaceability of the ion is quantified by the ratio of static to high-frequency  $\epsilon$ , which is almost ten times higher in halide perovskites as compared to other ionic, and covalent materials. These relaxed charge carriers are broadly termed as polaron, and classified according to the interaction governing the potential well depth, and size.

Fröhlich-like large polaron shows a narrow peak corresponding to the free excitons (FE), whereas the Holstein-like small polarons having fundamentally different features, are attributed to the STE with high stokes shift, and substantial lattice distortion.<sup>74,75</sup> A small polaron localised in a confined lattice site enables the interaction between the charge carrier and phonon. The halide perovskites have low frequency LO phonon mode due to the presence of heavy metal ions. The linewidth of the phonon absorption is generally broad at room temperature which is an indication of phonon overdamping. The soft lattice nature of halide perovskites creates large phonon anharmonicity which causes this overdamping.<sup>76</sup> Any local distortions *i.e.* bond angle or bond length variation, inorganic framework tilting, or doping, modify the coulombic interaction forming the small polarons. The incoherent atomic motion localizes the charge carriers, and alter the parent band structure. In this context, the potential depth of the STE state from the CBM is vital to direct the optical properties of halide perovskites. When the energy of self-trapping depth ( $E_{\text{depth}}$ ) is large, the de-trapping of carriers and back transfer from STE to CBM is an energetically unfavourable phenomenon. However, the back transfer becomes allowed, when the barrier is small. If  $E_b$  is greater than the thermal activation energy (26 meV at room temperature), BE emission dominates over the STE emission.

## 2D halide perovskites with multiple metal centers

### Participation of two discrete metal centers in HLDPs

In HLDPs, the alternate octahedra of the inorganic layer are constituted of heavy main group trivalent metal centers such as M(III): Bi<sup>3+</sup>, Sb<sup>3+</sup>, or In<sup>3+</sup>, and the monovalent M(I) ions: Ag<sup>+</sup> (Fig. 5a).<sup>11,77</sup> The inorganic layers are separated by a single, or double layer of organic amines to generate the RP and DJ phases, respectively. The HLDP structure can be visualized to be derived from the double perovskites [Cs<sub>2</sub>M(I)M(III)X<sub>6</sub>] by slicing along (100) planes, to generate the ⟨100⟩ oriented (A'<sub>4</sub>/A''<sub>2</sub>)M(I)M(III)X<sub>8</sub>, where the bulky organic spacers are denoted by a monoamine (A'), or diamine (A'').<sup>42</sup> The DJ HLDP structures, A''<sub>2</sub>AgM(III)X<sub>8</sub> may also consist of Mo<sup>3+</sup>, Ru<sup>3+</sup>, and Fe<sup>3+</sup>, having distinct magnetic properties.<sup>78,79</sup> The HLDPs are also stabilized by the hydrogen bonding interactions between the halide ions, and the NH<sub>3</sub><sup>+</sup> groups of the organic spacer. 1,4 Diamino butane (4N4) in combination with Ag(I)/Bi(III), and Ag(I)/Sb(III) pairs forms stable HLDP phases.<sup>11</sup> Changing the 4N4 to a bulkier diammonium spacer (1,6 diamino hexane; 6N6) alters the HLDP phase into the 1D (6N6)SbBr<sub>5</sub>. The 1D structure do not contain any Ag<sup>+</sup> center, because of its higher ionic radius of 1.15 Å, that does not allow it to be accommodated in the neighbouring octahedra along with Bi<sup>3+</sup> (1.03 Å), or Sb<sup>3+</sup> (0.76 Å). On transitioning from the bromide to iodide composition, the iodide phases with Ag(I)/Bi(III), and Ag(I)/Sb(III) are also devoid of Ag<sup>+</sup>, because of the reluctance of Ag<sup>+</sup> to form AgI<sub>6</sub><sup>5-</sup> octahedra.<sup>80</sup> There are only a very few reports where aerometric interactions between aryl amines that stabilize the iodide HLDPs to form



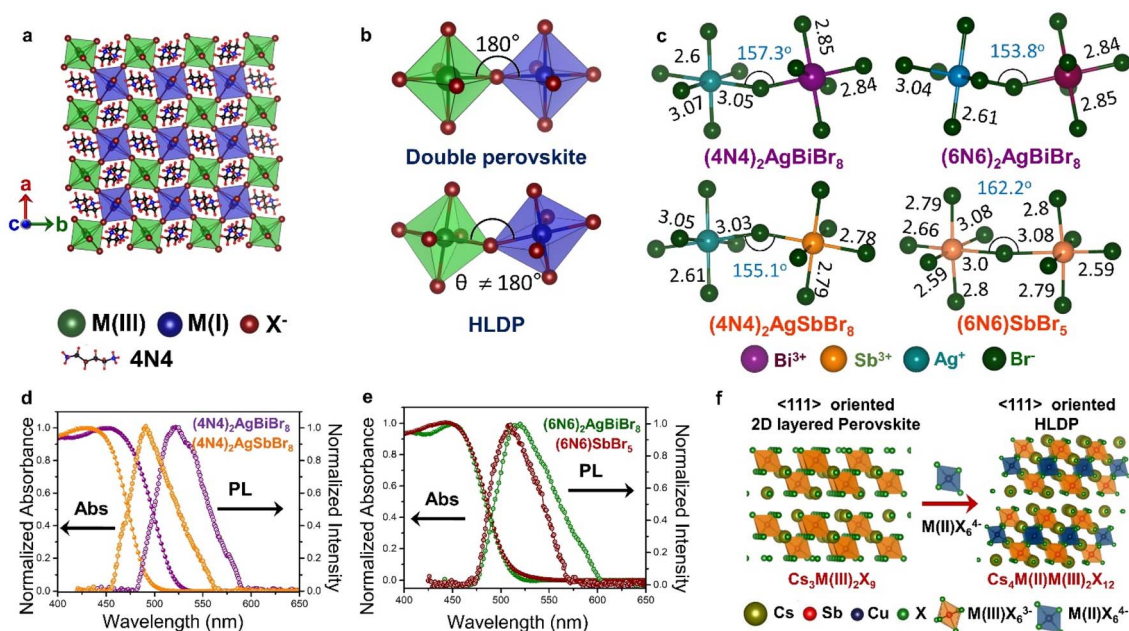


Fig. 5 Schematic representation of (a) the octahedra with M(III) and M(I) centers in the inorganic layer of double perovskite, and HLDP, and (b) the corresponding octahedral tilting. (c) Variations of bond length (in Å) and bond angle (in degrees) in  $(4N4)_2AgBiBr_8$ ,  $(4N4)_2AgSbBr_8$ ,  $(6N6)_2AgBiBr_8$ , and  $(6N6)SbBr_5$ .<sup>11</sup> Optical absorption, and PL spectra of (d)  $(4N4)_2AgBiBr_8$ , and  $(4N4)_2AgSbBr_8$ , and (e)  $(6N6)_2AgBiBr_8$ , and  $(6N6)SbBr_5$ .<sup>11</sup> (f) Schematic for the formation of LDPs from single layered  $\langle 111 \rangle$  oriented perovskites. Reproduced with permission from ref. 11, copyright (2023) Royal Society of Chemistry.

$(AE_2T)_2AgBiI_8$  ( $\{AE_2T = 5,5\text{-diylbis}-(\text{aminoethyl})-[2,2\text{-bithiophene}]\}$ ), and  $[(R/S)\text{-}\beta\text{-MPA}]_4AgBiI_8$  ( $[(R/S)\text{-}b\text{-MPA} = (R/S)\text{-}(\pm)\text{-}b\text{-methylphenylammonium}]$ ).<sup>80,81</sup>

Unlike the 3D double perovskites having  $M(III)\text{-}X\text{-}M(I)$  angles of  $180^\circ$ , the HLDPs exhibit considerable octahedral tilting (Fig. 5b), and a variation of bond lengths, especially due to extreme bond length variations in the  $AgX_6^{5-}$  octahedra (Fig. 5c).<sup>78</sup> Due to the alternately placed  $MBr_6^{3-}$  and  $AgBr_6^{5-}$  octahedra, a higher degree of octahedral tilting is observed for the HLDP structures as compared to the 1D  $(6N6)SbBr_5$  (Fig. 5c). The octahedral distortion also increases, when the spacer layer thickness increases from 4N4 to 6N6. As mentioned previously, the nature of the organic spacers, monoamine or diamine, as well as the spacer chain length, determine the stacking pattern of the respective octahedra. While 4N4 always forms the DJ-type HLDPs, where the inorganic layers lie on top of each other in the (0,0) pattern, the inorganic layers connected by the monoammonium cations, shift to form (1/2, 1/2) stacking in the RP analogues.<sup>42</sup> The HLDPs having smaller diamine spacers, such as 1,3 diamino propane, exhibit the (1/2, 0) type stacking pattern.<sup>78</sup>

The optical properties of the HLDPs are primarily controlled by M(III), more than the spacer (Fig. 5d and e). The bromide HLDPs usually display absorption edges below 500 nm. The substitution of  $Bi^{3+}$  with  $Sb^{3+}$  or  $In^{3+}$  causes a bluer shift of the absorption edges. The absorption and PL spectra do not differ much with the spacer chain length (Fig. 5d and e), but are red shifted from bromide to iodide, since the red-coloured iodide HLDPs display absorption edges

above 600 nm. In contrast, the chlorides exhibit a wide range of absorption, from UV to near IR, depending on the metal composition. The  $Ag(I)/In(III)$  HLDP chlorides with band gap above 3 eV absorb in the UV region. When  $In(III)$  is replaced by  $Mo(III)$  or  $Ru(III)$ , the band gap is lowered below 2 eV. HLDPs display compelling electronic properties in terms of direct and indirect band gaps, depending on the trivalent metal center, and the amine spacers. The  $Ag(I)/Bi(III)$  HLDPs with 4N4 spacer [ $(4N4)_2AgBiBr_8$ ] exhibit direct band gap, unlike the 3D counterpart, *i.e.*,  $Cs_2AgBiBr_6$ .<sup>11</sup> The indirect to direct band gap transition, with the lowering of dimensions, can be explained by molecular orbital theory. For example, the contribution of only Ag-s orbital at the valence band maximum (VBM), and Bi-p orbital at CB leads to direct band gaps.<sup>8</sup> The nature of the band gap also depends on the metal center, such as  $Ag(I)/Sb(III)$  HLDPs display direct band gaps,<sup>11</sup> whereas  $Ag(I)/In(III)$  HLDPs have indirect band gaps.<sup>77</sup> With the increase of spacer chain length from 4N4 to 6N6, the band gap can also change from direct to indirect.

### Vacancy ordered layered double perovskites

Besides the  $\langle 100 \rangle$  oriented HLDPs, the  $\langle 111 \rangle$  oriented layered halide perovskites are created by introducing vacancy. By substituting M(I) in  $Cs_2M(I)M(III)X_6$  with M(II), and a vacancy,  $\langle 111 \rangle$  oriented  $Cs_4\Box M(II)M(III)_2X_{12}$  ( $\Box =$  vacancy and  $M(II) =$  bivalent metal center) can be obtained.<sup>82</sup> The layered double perovskites (LDPs) are also known as multiple-layered  $\langle 111 \rangle$  perovskites. The single layered  $\langle 111 \rangle$  oriented  $Cs_3\Box M(III)_2X_9$  is converted into the LDP, by the incorporation of  $M(II)X_6^{4-}$



octahedra (Fig. 5f). In  $\text{Cs}_4\text{CuSb}_2\text{Cl}_{12}$  with a band gap of  $\sim 1$  eV,  $\text{Cu}^{2+}$  exhibits near IR absorption,<sup>82</sup> whereas the  $\text{Cd}^{2+}$  or  $\text{Mn}^{2+}$  centers in  $\text{Cs}_4\text{CdSb}_2\text{Cl}_{12}$  and  $\text{Cs}_4\text{MnSb}_2\text{Cl}_{12}$  increase the band gap.<sup>83,84</sup>

The alloying of metal centers is another prospective method to tune the optoelectronic properties of the layered halide perovskites. The high-entropy alloying in vacancy-ordered cubic double-perovskite,  $\text{Cs}_2\text{MCl}_6$  ( $\text{M} = \text{Zr}^{4+}, \text{Sn}^{4+}, \text{Te}^{4+}, \text{Hf}^{4+}, \text{Re}^{4+}, \text{Os}^{4+}, \text{Ir}^{4+}$  or  $\text{Pt}^{4+}$ ), produces multiple distinctly isolated octahedral units, giving rise to the complex vibrational and electronic structures.<sup>85</sup> Instead, the B-site alloying is regulated by thermodynamic factors. In RP  $(\text{BA})_2(\text{MA})_{n-1}\text{Pb}_x\text{Sn}_{n-x}\text{Br}_{3n+1}$ , and DJ  $(3\text{AMPY})(\text{MA})_{n-1}\text{Pb}_x\text{Sn}_{n-x}\text{Br}_{3n+1}$  ( $n = 1-3$ ), the  $\text{Pb}^{2+}$ -rich layer is more thermodynamically favoured, whereas, when  $n = 1$ , alloying of  $\text{Sn}^{2+}$  becomes difficult. At higher  $n$  values, the probability of B-site alloying increases, with a simultaneous variation in the electronic and optical properties.<sup>86</sup>

## 2D nanostructures

In layered halide perovskites, the inorganic octahedral layers connected by the organic ammonium cations, are often assembled in a harmonic periodic array, transforming the inorganic building blocks into periodically stacked NPLs, forming a superstructure, also referred to as perovskite superlattice.<sup>17</sup> The formation of a superlattice depends on the synthetic methods, such as template-based slow evaporation, ligand-assisted reprecipitation (LARP), standard hot injection (HI) method, *etc.* In the LARP method, the precursor salts and the organic acid-base pair, or the pre-synthesized single crystals are dissolved in a solvent, followed by the addition of an anti-solvent (*e.g.*, toluene, isopropanol) for the precipitation of the NPLs. While the organic amine molecule acts as the spacer cation, the acid counterpart passivates the nanostructure surface. The inclusion of two amine spacer molecules thereby changes the periodicity ( $\Delta$ ) of the NPL stacking.<sup>87,88</sup> In the HI method, a low enough temperature, and the precision in selecting the ratio of organic acid and amine pair are crucial for stabilizing the superlattice.<sup>89</sup> The intended 2D phase can also be achieved by introducing a foreign metal at the B-site (Fig. 6a). Designing the inorganic layers with the combination of two metal centers, is a bit tricky art for the NPL superlattice assembly.

One of the unique features of these 2D superlattices is the multilayer diffraction, similar to those of the NCs, packed with a periodic layout.<sup>17</sup> Here the split is mostly observed at the first Bragg peak, but not for the second. The X-ray scattering from a periodic packing of the NPLs results in interference fringes due to the constructive interference between the scattered X-rays from neighbouring NPLs. The degree of stacking in such an ordered structure influences the multilayer diffraction. The NPLs made by the inorganic octahedra constitute the most electron-dense part, resulting in stronger diffraction intensity, and higher scattering factor compared to the organic spacer. The superlattice periodicity ( $\Delta$ ) can be extracted directly from Bragg's diffraction. The scattering (momentum) vector  $q$  ( $\text{nm}^{-1}$ ), and the order of the superlattice reflection ( $n$ ) are

related to the Bragg angle ( $\theta$ ), and X-ray wavelength ( $\lambda$ ), according to the following equations:

$$q = \left(\frac{4\pi}{\lambda}\right) \sin \theta (\theta \text{ in radians}) \quad (4)$$

$$2 \sin \theta_n = n\lambda/\Delta \quad (5)$$

$$q_n = 2\pi n/\Delta \quad (6)$$

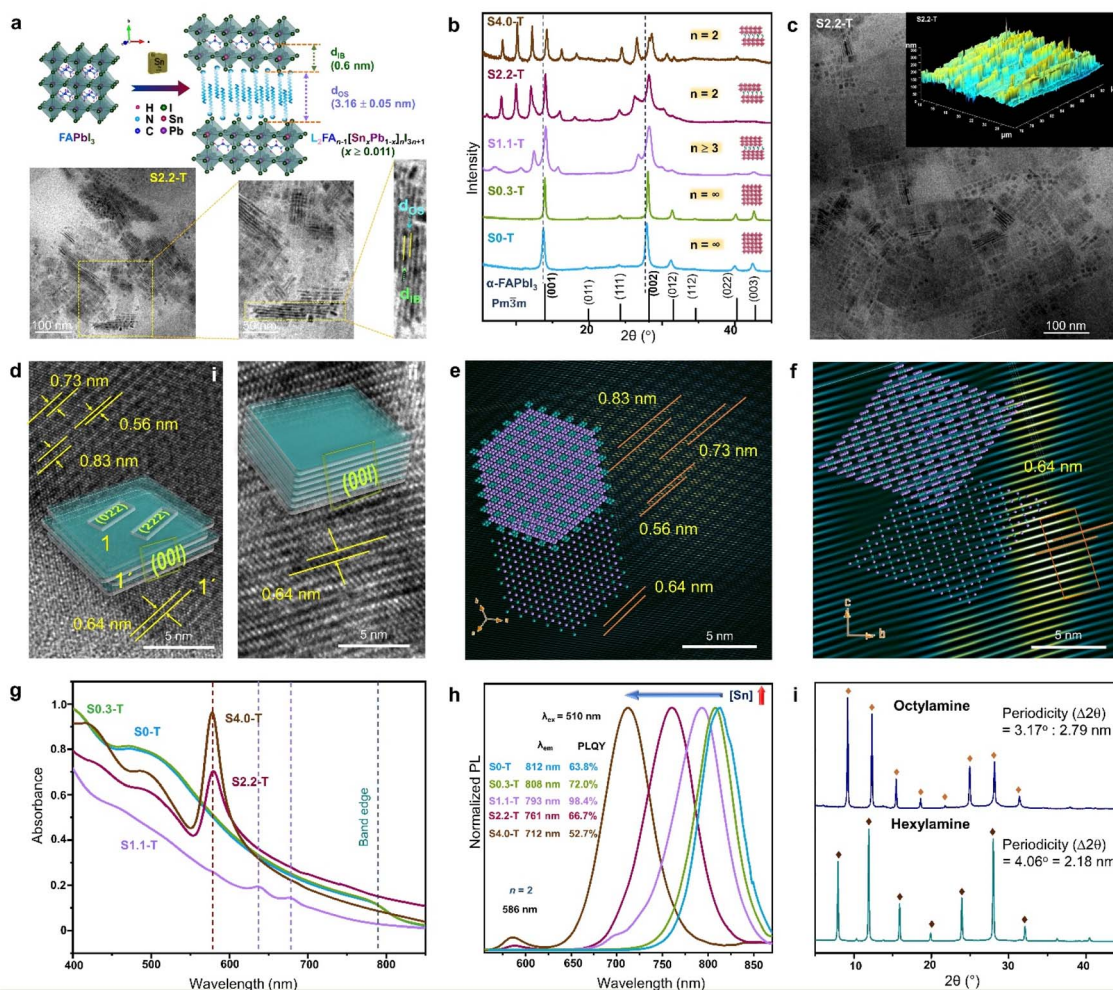
Since the peaks are periodic,  $\Delta$  is related to  $\Delta q$ , according to eqn (7):

$$\Delta q = q_{n+1} - q_n = 2\pi/\Delta \quad (7)$$

From the Gaussian fit profile of the multilayer diffraction and corresponding  $q$  vs.  $n$  plot,  $\Delta$ , and the organic layer thickness can be evaluated.  $\Delta$  measures the extent of disorder with two major contributing parameters,  $\sigma_L$  (inhomogeneity of the organic layer), and  $\sigma_N$  (NC/NPL stacking fault). An ordered face-to-face arrangement of the NPLs decreases the  $\sigma_L$  ( $\sim 0.5$ ), compared to the NCs. The multilayer diffraction of assembled NCs or NPLs becomes evident from small angle X-ray scattering, and grazing incidence wide angle X-ray scattering.<sup>90</sup> However, the NPLs are not adequately described by a unit cell or structure factor because of their crystal truncation, and different surface terminations.

The introduction of  $\text{Sn}^{2+}$  in the virgin structure of  $\text{FAPbI}_3$  results in the transformation of  $\text{FASn}_x\text{Pb}_{1-x}\text{I}_3$  ( $x < 0.011$ ) NCs into NPLs which become self-assembled to form the RP-like superlattice, with gradual increase of  $[\text{Sn}^{2+}]$  (Fig. 6a and b).<sup>89</sup> The generic formula of the RP-like superlattice structure is  $\text{L}_2\text{A}_{n-1}[\text{B}'_x\text{B}_{1-x}]_n\text{X}_{3n+1}$  where L = spacer amine, A = smaller amine cations like  $\text{Cs}^+$ ,  $\text{MA}^+$ ,  $\text{FA}^+$ , B and B' are  $\text{Pb}^{2+}$ , and  $\text{Sn}^{2+}$ , and X is the halide. As depicted in Fig. 6a,  $\Delta$  is the summation of the thickness of spacer cations ( $d_{\text{os}}$ ), and one slab of the inorganic layer ( $d_{\text{IB}}$ ). For  $\text{L}_2\text{FA}_{n-1}[\text{Sn}_x\text{Pb}_{1-x}]_n\text{I}_{3n+1}$  ( $x \geq 0.011$ ), the length of one octahedra is 0.6 nm, and the thickness of the oleylamine bilayer ( $d_{\text{os}}$ ) is  $3.16 \pm 0.05$  nm. The powder X-ray diffraction (PXRD) pattern shows that S0.3-T ( $x = 0.003$ ) conforms to the cubic phase (Fig. 6b). The Sn/Pb ratio of 0.01 (S1.1-T,  $n \geq 3$ ) is the initiation point of the multilayer diffraction of the (001) Bragg peak. With increasing  $\text{Sn}^{2+}$  concentration, S2.2-T ( $x = 0.022$ ), and S4.4-T ( $x = 0.044$ ) display the diffraction pattern with a specific periodicity ( $\sim 2^\circ \pm 0.05$ ) corresponding to the  $n = 2$  phase. Transmission electron microscopy (TEM), atomic force microscopy (AFM) also displays the evolution of the RP-like stacked NPLs (Fig. 6a and c). In S2.2-T, the stacking is either offset at the NPL edges (Fig. 6d(i)), or occurs exactly above each other along  $[00l]$  (Fig. 6d(ii)). The domain depicting the lateral offset of the NPL edges closely resembles the state of S1.1-T, where the stacking is incomplete. The lattice fringes corresponding to the satellite reflections of (001) plane ( $2\theta \sim 13.9^\circ$ , 0.64 nm) can be observed at  $2\theta \sim 10.6^\circ$  (0.83 nm),  $12.4^\circ$  (0.73 nm), and  $15.7^\circ$  (0.56 nm). Among them, (004) appears from the NPL edges, while (022) and (222) planes reside on the NPL top faces (inset schematic of Fig. 6d(i)). From the FFT mask





**Fig. 6** (a) Schematic showing the transformation of 3D  $\text{FAPbI}_3$  NCs to 2D RP superlattice of  $\text{L}_2\text{FA}_{n-1}[\text{Sn}_x\text{Pb}_{1-x}]_n\text{I}_{3n+1}$  ( $x \geq 0.011$ ), and the TEM analysis of S2.2-T NPL superlattice. Sequentially magnified TEM images show the superlattice structure, and its correlation with  $\Delta = d_{\text{IB}} + d_{\text{OS}} = 4.35 \pm 0.06$  nm. IB and OS represent the inorganic block with  $n = 2$ , and the organic spacer, respectively. (b) PXRD patterns with increasing Sn/Pb ratio, illustrating the gradual phase change from cubic NCs to 2D RP NPLs. (c) TEM image, and AFM image (inset) for the S2.2-T superlattice. (d) TEM images and schematics showing the NPL stacking with (i), and without (ii) edge offset. FFT mask filter analysis of the NPLs with (e) edge offset stacking, and (f) perfect stacking. The lower left insets show the model crystal lattice of a single NPL, and upper left insets demonstrate the stacking of four lattice planes. (g) Optical absorbance spectra, and (h) PL spectra ( $\lambda_{\text{ex}} = 510$  nm) of S0-T, S0.3-T, S1.1-T, S2.2-T and S4.0-T. (i) XRD patterns of the RP NPLs ( $x = 0.022$ ,  $n = 2$ ) with hexylamine and octylamine as the spacer. Reproduced with permission from ref. 89, copyright (2023) WILEY-VCH Verlag GmbH & Co. KGaA, Weinheim.

filter analysis, a model crystal lattice from a single NPL (Fig. 6e lower left inset) shows the four lattice planes juxtaposed on each other (Fig. 6e upper left inset). Fig. 6d(ii) shows the organised linear arrangement of the reciprocal lattice points of the (00 $l$ ) planes, portraying a near-perfect superlattice (Fig. 6f). It is intriguing how the lesser inert pair effect of the  $\text{Sn}^{2+}$  species than  $\text{Pb}^{2+}$  can have a more facile binding to the ligands, and transform the NCs into the NPL superlattices, even though  $\text{Sn}^{2+}$  is present in a miniscule amount.

The halide perovskite superlattices or superstructures exhibit fascinating optical properties including high PLQY, and superfluorescence.<sup>91</sup> Since the absorption and PL characteristics is strongly synchronized with the structural evolution, there are clear differences in the profiles between the NCs and NPL superlattices. In the above example, the absorbance profile of

S0.3-T NCs is similar to bulk  $\text{FAPbI}_3$  (Fig. 6g). In the case of incomplete stacking of the NPLs in S1.1-T, two absorption bands emerge, and finally, an intense excitonic band  $\sim 578$  nm becomes visible in the ordered superlattices of S2.2-T and S4.0-T. With increasing Sn content, the STE emission band is blue shifted along with the appearance of a small band  $\sim 586$  nm (Fig. 6h). The 586 nm PL band is attributed to the gradual appearance of the RP-like superlattice with  $n = 2$ . The highest PLQY of  $\sim 98.4\%$  is observed for S1.1-T ( $n \geq 3$ ), when the NPLs are capped by trioctylphosphine, which binds to the under-coordinated sites for minimising the surface defects. The periodicity of the multilayer diffraction can be altered by changing the spacer chain length. Smaller spacer cations increase the NPL stacking periodicity which is also reflected in the PXRD patterns (Fig. 6i). Till date, major focus is devoted to elucidate



the structural richness of the perovskite superlattices having multilayer diffraction. Their applications in LED technology, solar cells, FETs, and photodetectors are yet to be explored.

## Optoelectronic properties

The optoelectronic devices based on 3D halide perovskites are based on the need for enhancing the carrier mobility, restricting the ion migration channels, and protecting the hybrid framework against the penetration of moisture or oxygen. While it is challenging to navigate the carrier pathways through the complex ligand capped NC films,<sup>24,92</sup> the pliability of the NSs make them more promising.<sup>93,94</sup> The layered halide perovskites equipped with hydrophobic organic amine spacers can alleviate the disadvantages of moisture instability, and ion migration. The richness of the 2D systems lie in the compositional varieties of the inorganic octahedra, and the spacer layer thickness. Different varieties of 2D halide perovskites have been tested in the photovoltaic devices,<sup>94</sup> and optoelectronic applications such as LEDs,<sup>95</sup> FETs,<sup>96</sup> X-ray detectors,<sup>97</sup> and photodetectors.<sup>98</sup> The lead-free layered halide perovskites, featuring bulky organic spacers like phenylethylammonium (PEA) or thiophene methylammonium (TEA), hold promise for various optoelectronic applications. The LEDs based on (TEA)<sub>2</sub>SnI<sub>4</sub> and (PEA)<sub>2</sub>SnI<sub>4</sub> demonstrate external quantum efficiency (EQE) values of 0.62% and 1%, respectively.<sup>99,100</sup> Furthermore, the Sn-based layered halide perovskites show superior performance in terms of hole mobilities when utilized in the FET devices. The FET with (PEA)<sub>2</sub>SnI<sub>4</sub> and (4Tm)<sub>2</sub>SnI<sub>4</sub> [4Tm = 2-(3''',4'-dimethyl-[2,2':5',2'':5'',2''':5''''-quaterthiophen]-5-yl) ethan-1-ammonium] as the active layer exhibit appreciable hole mobilities of 15, and 2.32 cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>, respectively, along with enhanced stability compared to the 3D halide perovskites.<sup>101,102</sup>

In this context, we have discussed the adaptability of layered halide perovskite photoabsorbers, particularly focusing on their application in photodetectors. The escalating demands in fields such as optical communication, imaging, portable electronics, sensing, biomedical diagnosis, and soft robotics components underscore the immense relevance of photodetectors. Conventional photodetectors typically need an applied external electric potential (bias) across the device, whereas the self-powered photodetectors eliminate this need. The self-powered devices are self-reliant, portable, sustainable, capable of functioning in harsh conditions, and easily integrated with other devices. There are limited reports on self-powered photodetectors based on layered halide perovskites in the literature, representing an area ripe for exploration. The photodetection is measured either with the out-of-plane and in-plane architectures (Fig. 7a). The devices consist of an electron transport layer (ETL) made of compact TiO<sub>2</sub>, deposited on the top of fluorine doped tin oxide (FTO) substrate, followed by the perovskite layer, and Au/Ag as the contact electrode.

### Photodetectors of HLDPs

The HLDPs exhibit an appreciable wavelength-dependent photodetection in terms of the parameters such as

responsivity ( $R$ ), detectivity ( $D$ ), and EQE, at a certain applied voltage (Fig. 7b and c).<sup>11</sup> While the 2D arrangement of the inorganic octahedra allows a facile flow of the photo-generated charge carriers, the 1D hybrid halides constrict the mobility. The carrier flow is even more restricted in the 0D perovskite dimers such as Cs<sub>3</sub>M<sub>2</sub>I<sub>9</sub> (M = Bi<sup>3+</sup>, Sb<sup>3+</sup>) having disconnected inorganic units.<sup>103,104</sup> The ambient-stable Bi<sup>3+</sup> and Sb<sup>3+</sup> containing HLDPs can be used as self-powered photodetectors because of the favourable juxtaposition of the VBM and CBM with the ETL, and fermi energy of the metal contact. Moreso, the electronic communication can be substantially increased by lowering the separation between the inorganic layers. As shown in Fig. 7b, (4N4)<sub>2</sub>AgBiBr<sub>8</sub> with a lower separation across the 4-C spacer shows greater values of  $R$  and EQE than the 6N6 counterpart.<sup>11</sup> (4N4)<sub>2</sub>AgBiBr<sub>8</sub> shows a  $R$  of  $18.8 \pm 0.2$  A W<sup>-1</sup>, and EQE of  $6360 \pm 58\%$  at 2.5 V, under 370 nm (27 mW cm<sup>-2</sup>) illumination. In self-powered mode, (4N4)<sub>2</sub>AgBiBr<sub>8</sub> has the maximum  $R$  of 0.67, and 0.36 mA W<sup>-1</sup> under 370 nm, and visible light illumination. Additionally, the Sb-based hybrid halides with higher optical band gaps, show lower photo-detection ability than the Bi hybrids (Fig. 7b). Under similar illumination, (4N4)<sub>2</sub>AgSbBr<sub>8</sub> has a  $R$  of  $8.6 \pm 0.2$  A W<sup>-1</sup>, and EQE of  $2880 \pm 58\%$  at 2 V. The 1D hybrid halides, (4N4)-BiI and (4N4)-SbI, show wavelength dependent photoresponse. In the self-powered mode, (4N4)-SbI has a better  $R$  of 11.7 mA W<sup>-1</sup> under 485 nm illumination.

### Impact of halide composition in 2D Sn-perovskite photodetectors

The variation in chain length of the organic spacer cations manifests an attenuation of the QW barrier of the layered halide perovskites that alters the photodetection under potential bias, and self-powered conditions. A decrease in the spacer layer thickness from 8N8 to 4N4, decreases the interplanar distance ( $d$ ), and therefore increases the  $\Delta 2\theta$  interval of the equidistant (00 $l$ ) reflections.<sup>23</sup> The halide composition also has a tremendous impact on the optoelectronic performance. Although the iodide perovskites exhibit lower optical band gap, increasing the iodide content aggravates the issue of halide ion migration. As a result, the contrasting effect of halide ions and spacer chain lengths is reflected in the photodetection property of the out-of-plane devices. The mixed halide (8N8)SnBr<sub>2</sub>I<sub>2</sub> (8N8-Br/I) has lower band gap than (8N8)SnBr<sub>4</sub> (8N8-Br), and better phase purity than (8N8)SnI<sub>4</sub> (8N8-I). Incorporating the iodide extends the photodetection in the wide spectral range. All the devices show wavelength and intensity-dependent photodetection under applied potential bias, and self-powered conditions. Since the photodetection parameters are inversely proportional to the illumination intensity ( $L_{\text{light}}$ ), the maximum  $R$ ,  $D$ , and EQE are obtained when  $L_{\text{light}}$  is much reduced at 485 nm.<sup>23</sup> In contrast, since 8N8-Br has optical absorption in the near UV region, the best photodetector performance is obtained at 370 nm. 8N8-Br/I has a  $R$  of 23.2 A W<sup>-1</sup>, and EQE of 5930% at 3 V under 485 nm illumination. A facile charge transfer, reduced charge trapping, and halide migration escalate the device photoresponse.



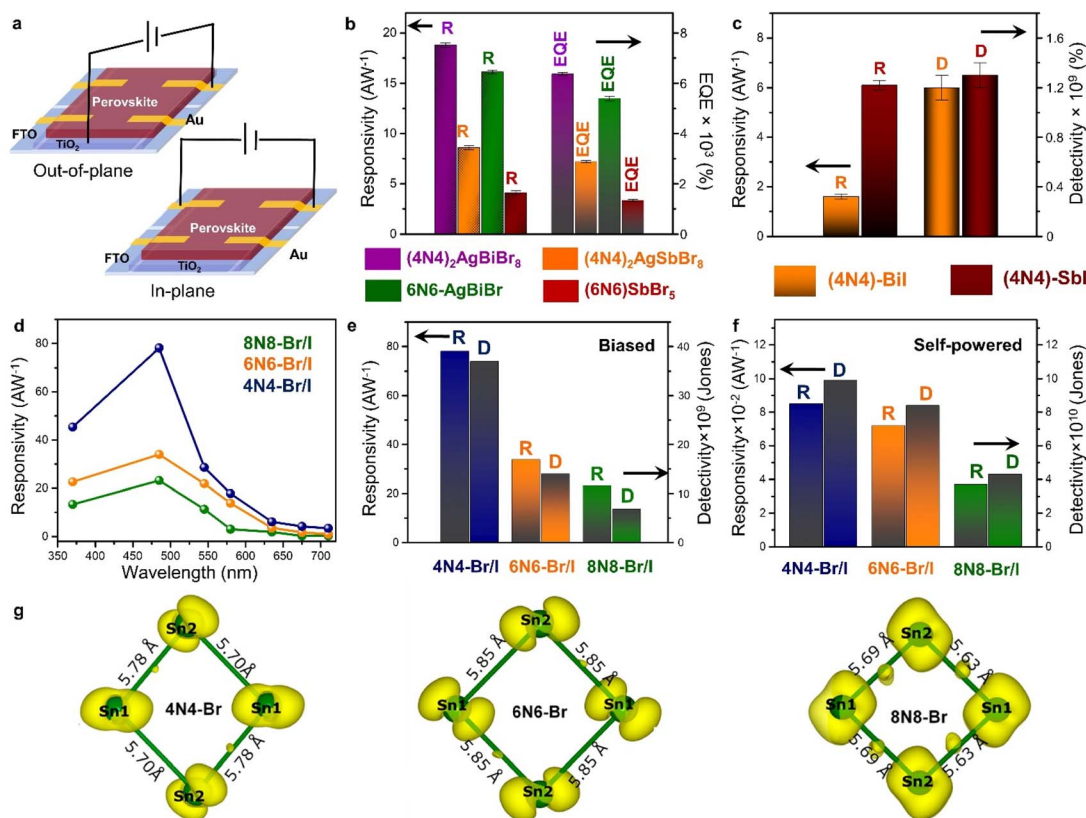


Fig. 7 (a) Schematic demonstration of the out-of-plane and in-plane photodetector devices. Statistical bar diagrams of (b)  $R$  and EQE (%) of the HLDP structures, and (c)  $R$  and  $D$  of 1D 4N4-BiI, and 4N4-SbI.<sup>11</sup> (d) Wavelength dependant variation of  $R$ , and statistical bar diagram of  $R$  and  $D$  under (e) potential-biased, and (f) self-powered conditions for the DJ ( $xN_x$ )Sn(Br/I)<sub>4</sub> ( $x = 8N8, 6N6, 4N4$ ).<sup>23</sup> (g) The spatially resolved charge density corresponding to the CBM of 4N4-Br, 6N6-Br, and 8N8-Br. The bond lengths of the inorganic network formed by the Sn atoms are also shown.<sup>23</sup> Reproduced with permission from ref. 11, copyright (2023) Royal Society of Chemistry, and ref. 23, copyright (2023) American Chemical Society of Chemistry.

### Impact of spacer layer thickness on photodetection

Since, the organic ammonium cation plays an important role in deciding the optoelectronic properties of the layered halide perovskite, its impact on the electronic and structural characteristics of the perovskite should be adjudged, along with its effect on the film quality. If the film quality, and roughness of the films are not altered significantly, the trend in the extent of charge transfer is majorly guided by the intrinsic factors. Maintaining the same composition in the inorganic framework, the layered halide perovskite with a shorter spacer thickness is expected to deliver better performance, due to lower interlayer separation between the inorganic units. The photodetectors with the shorter spacer (4N4-Br/I), therefore display higher current densities as a function of the applied potential (0–3 V) under an illumination of  $100 \text{ mW cm}^{-2}$ .<sup>23</sup> A maximum  $R$  of  $78.1 \text{ AW}^{-1}$  has been obtained for 4N4-Br/I at 485 nm under 3 V potential bias, much better than 6N6-Br/I, and 8N8-Br/I (Fig. 7d and e). The Sn-based mixed halide DJ perovskites also exhibit remarkable self-powered photodetection, where the maximum  $R$  and  $D$  for 4N4-Br/I are  $0.085 \text{ AW}^{-1}$ , and  $9.9 \times 10^{10} \text{ Jones}$ , respectively (Fig. 7f).<sup>23</sup> The minimized dark current density ( $J_D$ ) reinforces the  $D$  value in the absence of any potential bias.

A sustained current density ( $J_L$ ) under constant illumination can be validated from the chronoamperometry plots. With increasing light intensity, the current densities of the 4N4-Br/I self-powered devices increase up to a threshold point followed by a lowering of the current density. An intense illumination induces ion migration, and halide segregation leading to the degradation of the films. In contrast, the increased hydrophobic thickness in 6N6-Br/I, and 8N8-Br/I prevents the film degradation, despite having a lower  $J_L$  as compared to the 4N4-Br/I films.<sup>23</sup> The reduced rise time (RT) and fall time (FT), obtained from the chronoamperometry plots imply a fast photo-response under the self-powered condition for the 4N4-Br/I films.

A lower charge transfer resistance, higher hole mobility, and improved lifetime of the charge carriers, further emphasizes the advantage of a shorter spacer thickness in employing the layered halide perovskites in optoelectronic devices. A comparison between the DJ, and RP analogues of the Sn-based layered halide perovskites show that the DJ phases experience a relatively lower  $E_b$ , and higher extent of charge extraction. On the other hand, the van der Waals gap in between the organic bilayer of the RP phase reduces the charge extraction, and carrier mobility, resulting in a subservient photodetection





capability. As compared to the DJ 8N8-Br/I, the  $(8N)_2SnBr_2I_2$  (8N-RP-Br/I) RP phase shows a subdued  $R$  value of  $4.4 \text{ AW}^{-1}$ , and EQE of 1120% at 3 V under 485 nm illumination.<sup>23</sup>

### Role of descriptors

Generally, the high absorption coefficient of low band gap semiconductors is considered a favourable attribute for the photodetectors. In most cases, the optoelectronic descriptors namely, the band gap, effective mass, out-of-plane mobility, transition probability of band edge transition, and net volume of the perovskites can explain the optoelectronic trend as a function of spacer layer thickness.<sup>9,11</sup> In rare instances, the spin orientation at the VBM and CBM play a pivotal role in deciding the direct *vs.* indirect optical transitions.<sup>23</sup> In halide perovskites, structural distortions, and heavy elements create substantial spin-orbit interactions which lead to the spin texture in the VBM and CBM, despite the absence of any intrinsic magnetic property. Increasing spacer layer thickness can mould the spin-orbit coupling which modifies the wave function at the CBM and VBM, resulting in significant differences in their spin orientations. For example, the individual p-orbital contributions at the CBM are altered due to the admixture of the  $p_y$  orbital with the  $p_x$  orbital for the labelled Sn1 atom in 6N6-Br and 8N8-Br systems that arise from the structural distortions (Fig. 6e and 7g). Since the Sn p-orbital is not pointed towards the anion site, such a complex spin texture is observed which results in the direct and indirect transition probability with varying spacer chain length. The probability of direct transition increases from 8N8 to 4N4 systems. Due to the absence of any  $p_y$  orbital admixture at the CBM of 4N4-Br/I, the photodetection parameters are enhanced with the shortest 4N4 system. In case of 4N4-Br/I, the direct component is more than 95% at Sn1 and Sn2 centers, whereas for 8N8-Br/I, it decreases to  $\sim 74\%$ .<sup>23</sup> However, the major descriptor that can explain the trend of optoelectronics depends on the architecture of the layered halide perovskite lattice, wherein theoretical calculations, in combination with the experimental results, can resolve the paradox.

## Conclusions and perspective

Despite the toxic Pb-containing perovskites having achieved significant milestones in photovoltaics over the past decade, this perspective highlights the immense potential of lead-free alternatives in optoelectronics. Both Pb- and Sn-based hybrid perovskites exhibit favourable characteristics such as a decent band gap, strong absorption, low effective mass, and high mobility of the charge carriers, rendering them promising for various device applications. The Sn-center possesses a unique advantage in the form of active  $ns^2$  configuration with lesser inert pair effect than the  $Pb^{2+} 6s$  orbital. This allows a facile interaction with the surrounding ligands, enabling the moulding of the perovskite lattice, and structural dimensions.

In addition to the low-dimensional hybrid halides, HLDP phases, and vacancy ordered double perovskites, this perspective is particularly focused on the RP and DJ phases of  $Sn^{2+}$ -containing layered halide perovskite single crystals and NPL

superlattices. Beyond the single crystals, and depending on the LARP or HI synthesis, the inorganic octahedral layers can assemble into periodically stacked NPLs, cojoined by the organic amine, giving rise to a superlattice or superstructure. The synthesis of single crystals and nanostructures of layered halide perovskites relies on regulating thermodynamic parameters and the solubility of active precursors in the solution, yet there are nuanced differences in stabilizing each. Firstly, a high temperature is initially required to dissolve all the precursors, followed by cooling to a lower temperature for preparing the single crystals by acid precipitation. To synthesize the anisotropic layered nanostructures by HI method, high temperatures are disadvantageous, as they facilitate overcoming the activation energy needed for isotropic growth of the nanoparticles, rather than the desired anisotropic growth. Secondly, the nanostructures exhibit a preference for long-chain hydrophobic amines, such as oleylamine, to stabilize the periodic array of the NPLs. Conversely, the layered halide perovskite single crystals favour spacer amines with moderate chain lengths. Third, the single crystals can achieve the stabilization of  $n = 1$  phase, whereas, synthesizing pure  $n = 1$  phase layered nanostructures *via* the HI method in the Schlenk line is a considerable challenge. Fourth, the introduction of a foreign metal center in the parent structure presents another synthetic challenge. Single crystals exhibit resistance to alloying within the lattice structure of the layered halide perovskites. In contrast, the nanostructures are more receptive for incorporating the foreign metals into their lattice. However, this process requires a substantial stimulus, since a greater amount of foreign metal precursor is needed to infiltrate the lattice.

The optical properties of the layered halide perovskites are a function of the organic spacer layer thickness, the metal center, and the halide composition. In most cases, the distinct absorption and PL features have their origin in the STE emission guided by the structural deformation, octahedral tilting, and the polaronic effect. The STE emission-guided PLQY is more prominent in the presence of longer spacer cations. Even though the layered halide perovskite single crystals often exhibit a high PLQY, the assembled nanostructures demonstrate superfluorescence, also characterized by a high PLQY.

The layered halide perovskites hold substantial promise for LED applications due to their tuneable quantum confinement effect and high PLQY compared to their 3D counterparts. However, their potential in solar cells, and FETs is limited due to the presence of hydrophobic organic chains, which can hinder carrier mobility and the charge extraction process. In this context, the research on 3D/2D heterojunction solar cells has gained attention in the recent years. While these layered halide structures excel in LED applications, their suitability for commercial displays and laser applications is hindered by the presence of multiple emission peaks for  $n > 1$  phases, which compromises their phase, and colour purity. The long-term thermal and optical stability of single crystals, nanostructures, and devices in ambient atmospheric conditions poses another significant hurdle to the commercialization of these materials across various applications.



The extent of their optoelectronic performance is attuned by the excitonic band gap, dielectric constant, effective mass, carrier mobility, Rashba splitting, as well as the spin texture at the VBM and CBM. The shortest spacer chain length of the organic ammonium cation has so far demonstrated the most promising photodetector performance. In addition to the intrinsic descriptors, the optoelectronic performance relies on the quality of the photoactive layer, whether it's in the form of single crystals or polycrystalline films. While preparing large-area single crystals poses challenges due to their fragile and brittle nature, creating the pinhole-free and homogeneous polycrystalline films presents even greater difficulties. Single crystals are often synthesized in an acid solution, while organic solvents are typically used for film preparation *via* the spin-coating method. The thermodynamic and kinetic processes involved in the crystallization and growth of layered halide perovskite films are fundamentally distinct from those governing the growth of single crystals. To understand the effects of the spacer on device efficiency, a thorough analysis encompassing the growth mechanism, crystallinity, morphology, orientation, precise composition, interactions in multiple phases, phase selectivity, and stability of the film is essential.

To conclude, 2D halide perovskites offer ample opportunities ranging from single crystals to 2D superlattices, equipped with a rich and diverse variety of optical and optoelectronic properties. Beyond the photodetectors or solar cells, the lead-free layered halide perovskites exhibit diverse applications such as X-ray detectors, ferro- and antiferroelectric materials, and anti-counterfeiting agents, showcasing their versatility and potential across various technological domains. On the other hand, in the relatively new area of NPL superlattices, despite some focus on structural details, the potential of these long-range periodicity remains largely untapped in optoelectronics and photovoltaics, presenting a promising avenue for further exploration. Given the potential for a range of structural analogues, 2D halide perovskites hold promise for the advancement of modern electronics and next-generation renewable energy solutions.

## Author contributions

V. H., A. M. and S. B. conceptualized the idea, and co-wrote the perspective; S. B. supervised the entire project.

## Conflicts of interest

There are no conflicts to declare.

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